

## Description

The F1478 is a high gain, two-stage RF Amplifier designed to operate within the 1.8GHz to 5.0GHz frequency range. Using a single 5V power supply and only 140mA of  $I_{CC}$ , the F1478 provides 30.3dB of Gain and 1.6dB of Noise Figure with up to +35.73dBm OIP3 and 23.6dBm OP1dB at 3.55GHz.

The F1478 is packaged in a 3 × 3 mm, 16-VFQFPN, with matched 50Ω input and output impedances for ease of integration into the signal path.

## Competitive Advantage

- Combines a two-stage RF amplifier in a single, compact 3mm × 3mm VFQFPN package
- Excellent performance over exceptionally wide bandwidths
- Single device provides adjustable linearity versus current via an external resistor

## Typical Applications

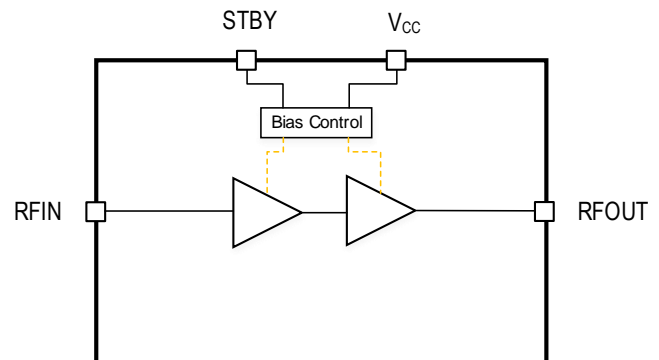
- 4G / 5G Cellular Basestations
- Multi-mode, Multi-carrier Transmitters
- Active Antenna Systems

## Features

- RF range: 1.8GHz to 5.0GHz
- 30.3dB typical gain at 3.55GHz
- 1.6dB NF at 3.55GHz
- Adjustable OIP3 performance
  - +35.7dBm OIP3 at 3.55GHz and 140mA of bias current
  - +32.2dBm OIP3 at 3.55GHz and 100mA of bias current
- Adjustable OP1dB performance
  - +23.6dBm OP1dB at 3.55GHz and 140mA of bias current
  - +22.8dBm OP1dB at 3.55GHz and 100mA of bias current
- 5V power supply
- Adjustable  $I_{CC}$  ranging from 80mA to 160mA
- 50Ω Single-ended Input and Output Impedances
- 1.8V Logic Compatible Standby Mode for Power Savings
- Operating temperature ( $T_{EPAD}$ ) range: -40°C to +115°C
- 3 × 3 mm 16-VFQFPN package

## Block Diagram

**Figure 1. Block Diagram**



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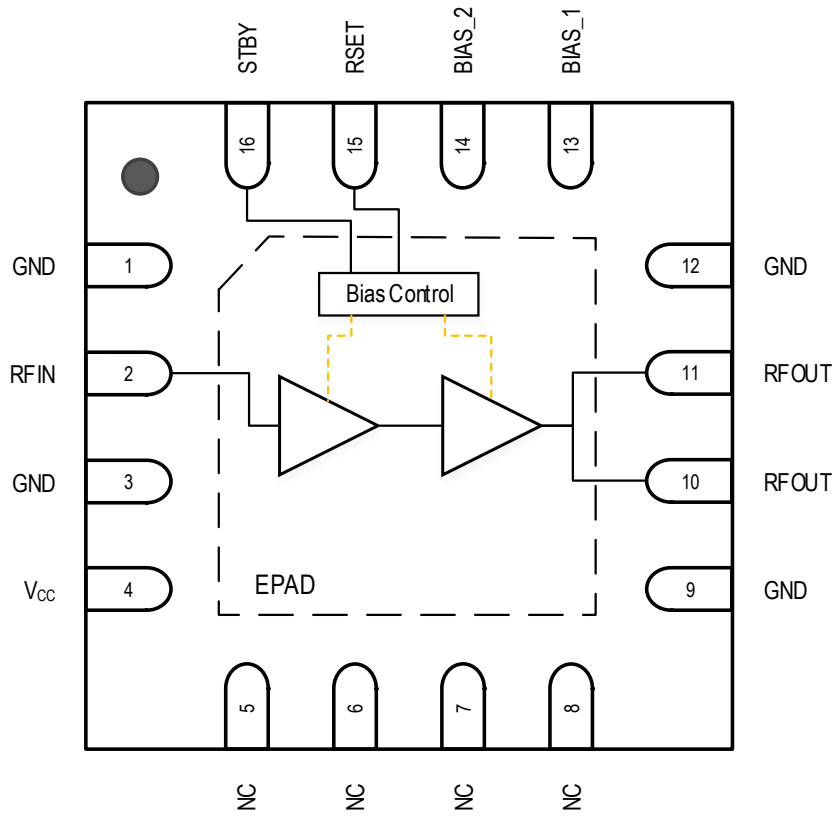
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## Pin Assignments

Figure 2. Pin Assignments for 3 × 3 × 0.9 mm VFQFPN Package – Top View



## Pin Descriptions

**Table 1. Pin Descriptions**

Number	Name	Description
1, 3, 9, 12	GND	Internally grounded. This pin must be grounded with a via as close to the pin as possible.
2	RFIN	RF input internally matched to 50Ω. Must use an external DC block.
4	V <sub>CC</sub> -RF	Pull up to V <sub>CC</sub> through inductor and use bypass capacitors as close to the pin as possible. In addition to supplying the device with a DC voltage, there is also an RF signal present.
5-8	NC	No internal connection. These pins can be left unconnected, or be connected to ground (recommended). Use a via as close to the pin as possible if grounded.
10, 11	RFOUT	RF output. Pull up to V <sub>CC</sub> through inductor. Must use external DC block.
13	BIAS_1	Connect via resistor to a common V <sub>CC</sub> and use bypass capacitors as shown in the Typical Application Circuit. Place network as close to the pin as possible.
14	BIAS_2	Connect via inductor to ground.
15	RSET	Connect via resistor to ground. Resistor value sets the device into its low or high power mode.
16	STBY	Standby pin. With Logic LOW applied to this pin the amplifier is powered off. With Logic HIGH applied to this pin (or if the pin is left unconnected), the part is in full operation mode. Pin is 1.8V logic compatible.
	— EPAD	Exposed Pad. Internally connected to ground. Solder this exposed pad to a PCB pad that uses multiple ground vias to provide heat transfer out of the device into the PCB ground planes. These multiple ground vias are also required to achieve the noted RF performance.

## Absolute Maximum Ratings

Stresses above those listed below may cause permanent damage to the device. Functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

**Table 2. Absolute Maximum Ratings**

Parameter	Symbol	Minimum	Maximum	Units
V <sub>CC</sub> to GND	V <sub>CC</sub>	-0.3	+6.0	V
STBY	V <sub>CTL</sub>	-0.3	Lower of (5.0, V <sub>CC</sub> + 0.25)	V
BIAS_1 (into pin)	I <sub>BIAS_1</sub>		20	mA
BIAS_2 (out of pin)	I <sub>BIAS_2</sub>		10	mA
RFIN externally applied DC voltage	V <sub>RFIN</sub>	-0.5	+0.5	V
RFOUT externally applied DC voltage	V <sub>RFOUT</sub>	-0.5	+5.5	V
Maximum CW Input Power applied for 24 hours. V <sub>CC</sub> = 5V, T <sub>EPAD</sub> = 115°C, input / output VSWR < 2:1 based on a 50Ω system. Standby = logic HIGH: ON state. [a]	P <sub>MAX_IN_ON</sub>		21	dBm
Maximum CW Input Power applied for 24 hour. V <sub>CC</sub> = 5V, T <sub>EPAD</sub> = 115°C, input / output VSWR < 2:1 based on a 50Ω system. Standby = logic LOW: OFF state.[a]	P <sub>MAX_IN_OFF</sub>		21	
Continuous Power Dissipation	P <sub>DISS</sub>		1.8	W
Storage Temperature Range	T <sub>st</sub>	-65	150	°C
Lead Temperature (soldering, 10s)			260	°C
ElectroStatic Discharge – HBM (JEDEC/ESDA JS-001-2012)	V <sub>ESDHBM</sub>		500 (Class 1B)	V
ElectroStatic Discharge – CDM (JEDEC 22-C101F)	V <sub>ESDCDM</sub>		1000 (Class C3)	V

[a] Exposure to these maximum RF levels can result in significantly higher I<sub>cc</sub> current draw due to overdriving the amplifier stages.

## Recommended Operating Conditions

**Table 3. Recommended Operating Conditions**

Parameter	Symbol	Condition	Minimum	Typical	Maximum	Units
Power Supply Voltage	$V_{CC}$		3.15		5.25	V
Operating Temperature Range	$T_{EPAD}$	Exposed Paddle	-40		+115	°C
Junction Temperature – Amplifier	$T_j$				150	°C
RF Frequency Range [a]	$f_{RF}$	Band 2p0 Tuning Set	1.8		2.2	GHz
		Band 2p5 Tuning Set	2.3		2.7	
		Band 3p5 Tuning Set	3.3		3.8	
		Band 4p7 Tuning Set	4.4		5.0	
RFIN Port Impedance	$Z_{RFI}$	Single Ended		50		$\Omega$
RFOUT Port Impedance	$Z_{RFO}$	Single Ended		50		$\Omega$

[a] Using external matching, gain flatness is optimized from 1.8GHz to 2.2GHz (Band 2p0 Tuning Set), 2.3GHz to 2.7GHz (Band 2p5H Tuning Set), 3.3GHz to 3.8GHz (Band 3p5 Tuning Set), and 4.4GHz to 5.0GHz (Band 4p7 Tuning Set).

## Electrical Characteristics – General

See Typical Application Circuit. Specifications apply when operated as a TX amplifier with tuning optimized for desired band of interest,  $V_{CC} = +5.0V$ ,  $T_{EPAD} = +25^{\circ}C$ ,  $STBY = HIGH$ ,  $Z_S = Z_L = 50\Omega$ , Evaluation Kit trace and connector losses are de-embedded, unless otherwise stated.

**Table 4. Electrical Characteristics**

Parameter	Symbol	Condition	Minimum	Typical	Maximum	Units
Logic Input High	$V_{IH}$		<b>1.17</b> <sup>[a]</sup>		$V_{CC}$	V
Logic Input Low	$V_{IL}$		<b>-0.3</b>		<b>0.63</b>	V
Logic Current	$I_{STBY}$	STBY	<b>-10</b>		<b>+10</b>	$\mu A$
Quiescent Current <sup>[b]</sup>	$I_{CC\_QL}$	Low Power Mode: $R3 = 16k\Omega$		100	130	mA
	$I_{CC\_QH}$	High Power Mode: $R3 = 10k\Omega$		140	178	
Standby Current	$I_{CC\_STBY}$	STBY = LOW		1.5		mA
Standby Switching Time	$t_{ON}$	50% STBY control to within 0.5dB of the on-state final gain value		270		ns
	$t_{OFF}$	50% STBY control to 30dBc below nominal gain value		60		

[a] Specifications in the minimum/maximum columns that are shown in **bold italics** are guaranteed by test. Specifications in these columns that are not shown in bold italics are guaranteed by design characterization.

[b]  $I_{CC}$  refers to the nominal small signal bias current.

## Electrical Characteristics – Band 2p0 (1.8GHz to 2.2GHz) / Low Power Mode

See Typical Application Circuit. Specifications apply when operated as a TX amplifier with tuning optimized for the 1.8GHz to 2.2GHz band,  $V_{CC} = +5.0V$ ,  $I_{CC} = 100mA$ ,  $R3 = 16k\Omega$ ,  $f_{RF} = 2.0GHz$ ,  $T_{EPAD} = +25^{\circ}C$ ,  $STBY = HIGH$ ,  $Z_S = Z_L = 50\Omega$ , Evaluation Kit trace and connector losses are de-embedded, unless otherwise stated.

**Table 5. Electrical Characteristics – Band 2p0 (1.8GHz to 2.2GHz) / Low Power Mode**

Parameter	Symbol	Condition	Minimum	Typical	Maximum	Units
Gain	G			29.1		dB
Gain Flatness	$G_{FLAT}$	$f_{RF} = 1.8GHz$ to 2.2GHz		0.7		dB
Gain Variation Over Temperature	$G_{TEMP}$	$T_{EPAD} = -40^{\circ}C$ to $+115^{\circ}C$ , referenced to $T_{EPAD} = 25^{\circ}C$		+0.7 / -1.6		dB
STBY Mode Gain	$G_{STBY}$	STBY = logic LOW $P_{IN} \leq -15dBm$ $f_{RF} = 1.8GHz$ to 2.2GHz		-45		dB
RF Input Return Loss	$RL_{RFIN}$	$f_{RF} = 1.8GHz$ to 2.2GHz		9.4		dB
RF Output Return Loss	$RL_{RFOUT}$	$f_{RF} = 1.8GHz$ to 2.2GHz		17.6		dB
Reverse Isolation	$ISO_{REV}$			50		dB
Noise Figure	NF			1.7		dB
Output Third Order Intercept Point	OIP3	$P_{OUT} = +2dBm$ / tone 1MHz tone separation		32		dBm
Output 1dB Compression Point	OP1dB			23.3		dBm

## Electrical Characteristics – Band 2p0 (1.8GHz to 2.2GHz) / High Power Mode

See Typical Application Circuit. Specifications apply when operated as a TX amplifier with tuning optimized for the 1.8GHz to 2.2GHz band,  $V_{CC} = +5.0V$ ,  $I_{CC} = 140mA$ ,  $R3 = 10k\Omega$ ,  $f_{RF} = 2.0GHz$ ,  $T_{EPAD} = +25^{\circ}C$ ,  $STBY = HIGH$ ,  $Z_S = Z_L = 50\Omega$ , Evaluation Kit trace and connector losses are de-embedded, unless otherwise stated.

**Table 6. Electrical Characteristics – Band 2p0 (1.8GHz to 2.2GHz) / High Power Mode**

Parameter	Symbol	Condition	Minimum	Typical	Maximum	Units
Gain	G			29.9		dB
Gain Flatness	$G_{FLAT}$	$f_{RF} = 1.8GHz$ to 2.2GHz		0.7		dB
Gain Variation Over Temperature	$G_{TEMP}$	$T_{EPAD} = -40^{\circ}C$ to $+115^{\circ}C$ , referenced to $T_{EPAD} = 25^{\circ}C$		+0.7 / -1.6		dB
STBY Mode Gain	$G_{STBY}$	STBY = logic LOW $P_{IN} \leq -15dBm$ $f_{RF} = 1.8GHz$ to 2.2GHz		-45		dB
RF Input Return Loss	$RL_{RFIN}$	$f_{RF} = 1.8GHz$ to 2.2GHz		8.0		dB
RF Output Return Loss	$RL_{RFOUT}$	$f_{RF} = 1.8GHz$ to 2.2GHz		16.0		dB
Reverse Isolation	$ISO_{REV}$			50		dB
Noise Figure	NF			1.8		dB
Output Third Order Intercept Point	OIP3	$P_{OUT} = +2dBm$ / tone 1MHz tone separation		34,8		dBm
Output 1dB Compression Point	OP1dB			24.0		dBm

## Electrical Characteristics – Band 2p5 (2.3GHz to 2.7GHz) / Low Power Mode

See Typical Application Circuit. Specifications apply when operated as a TX amplifier with tuning optimized for the 2.3GHz to 2.7GHz band,  $V_{CC} = +5.0V$ ,  $I_{CC} = 100mA$ ,  $R3 = 16k\Omega$ ,  $f_{RF} = 2.5GHz$ ,  $T_{EPAD} = +25^{\circ}C$ ,  $STBY = HIGH$ ,  $Z_S = Z_L = 50\Omega$ , Evaluation Kit trace and connector losses are de-embedded, unless otherwise stated.

**Table 7. Electrical Characteristics – Band 2p5 (2.3GHz to 2.7GHz) / Low Power Mode**

Parameter	Symbol	Condition	Minimum	Typical	Maximum	Units
Gain	G			29.3		dB
Gain Flatness	$G_{FLAT}$	$f_{RF} = 2.3GHz$ to 2.7GHz		0.6		dB
Gain Variation Over Temperature	$G_{TEMP}$	$T_{EPAD} = -40^{\circ}C$ to $+115^{\circ}C$ , referenced to $T_{EPAD} = 25^{\circ}C$		+0.7 / -1.0		dB
STBY Mode Gain	$G_{STBY}$	STBY = logic LOW $P_{IN} \leq -15dBm$ $f_{RF} = 2.3GHz$ to 2.7GHz		-46		dB
RF Input Return Loss	$RL_{RFIN}$	$f_{RF} = 2.3GHz$ to 2.7GHz		9.8		dB
RF Output Return Loss	$RL_{RFOUT}$	$f_{RF} = 2.3GHz$ to 2.7GHz		12.6		dB
Reverse Isolation	$ISO_{REV}$			49		dB
Noise Figure	NF			1.7		dB
Output Third Order Intercept Point	OIP3	$P_{OUT} = +2dBm$ / tone 1MHz tone separation		32.2		dBm
Output 1dB Compression Point	OP1dB			22.8		dBm

## Electrical Characteristics – Band 2p5 (2.3GHz to 2.7GHz) / High Power Mode

See Typical Application Circuit. Specifications apply when operated as a TX amplifier with tuning optimized for the 2.3GHz to 2.7GHz band,  $V_{CC} = +5.0V$ ,  $I_{CC} = 140mA$ ,  $R3 = 10k\Omega$ ,  $f_{RF} = 2.5GHz$ ,  $T_{EPAD} = +25^{\circ}C$ ,  $STBY = HIGH$ ,  $Z_S = Z_L = 50\Omega$ , Evaluation Kit trace and connector losses are de-embedded, unless otherwise stated.

**Table 8. Electrical Characteristics – Band 2p5 (2.3GHz to 2.7GHz) / High Power Mode**

Parameter	Symbol	Condition	Minimum	Typical	Maximum	Units
Gain	G			30.3		dB
Gain Flatness	$G_{FLAT}$	$f_{RF} = 2.3GHz$ to 2.7GHz		0.6		dB
Gain Variation Over Temperature	$G_{TEMP}$	$T_{EPAD} = -40^{\circ}C$ to $+115^{\circ}C$ , referenced to $T_{EPAD} = 25^{\circ}C$		+0.7 / -1.0		dB
STBY Mode Gain	$G_{STBY}$	STBY = logic LOW $P_{IN} \leq -15dBm$ $f_{RF} = 2.3GHz$ to 2.7GHz		-46		dB
RF Input Return Loss	$RL_{RFIN}$	$f_{RF} = 2.3GHz$ to 2.7GHz		11.9		dB
RF Output Return Loss	$RL_{RFOUT}$	$f_{RF} = 2.3GHz$ to 2.7GHz		10.6		dB
Reverse Isolation	$ISO_{REV}$			49		dB
Noise Figure	NF			1.6		dB
Output Third Order Intercept Point	OIP3	$P_{OUT} = +2dBm$ / tone 1MHz tone separation		35.7		dBm
Output 1dB Compression Point	OP1dB			23.6		dBm

## Electrical Characteristics – Band 3p5 (3.3GHz to 3.8GHz) / Low Power Mode

See Typical Application Circuit. Specifications apply when operated as a TX amplifier with tuning optimized for the 3.3GHz to 3.8GHz band,  $V_{CC} = +5.0V$ ,  $I_{CC} = 100mA^{[a]}$ ,  $R_3 = 16k\Omega$ ,  $f_{RF} = 3.55GHz$ ,  $T_{EPAD} = +25^\circ C$ ,  $STBY = HIGH$ ,  $Z_S = Z_L = 50\Omega$ , Evaluation Kit trace and connector losses are de-embedded, unless otherwise stated.

**Table 9. Electrical Characteristics – Band 3p5 (3.3GHz to 3.8GHz) / Low Power Mode**

Parameter	Symbol	Condition	Minimum	Typical	Maximum	Units
Gain	G		<b>27.9<sup>[a]</sup></b>	28.9		dB
Gain Flatness	$G_{FLAT}$	$f_{RF} = 3.3GHz$ to 3.8GHz		0.6		dB
Gain Variation Over Temperature	$G_{TEMP}$	$T_{EPAD} = -40^\circ C$ to $+115^\circ C$ , referenced to $T_{EPAD} = 25^\circ C$		+1.2 / -1.5		dB
STBY Mode Gain	$G_{STBY}$	STBY = logic LOW $P_{IN} \leq -15dBm$ $f_{RF} = 3.3GHz$ to 3.8GHz		-40		dB
RF Input Return Loss	$RL_{RFIN}$	$f_{RF} = 3.3GHz$ to 3.8GHz		12.8		dB
RF Output Return Loss	$RL_{RFOUT}$	$f_{RF} = 3.3GHz$ to 3.8GHz		9.6		dB
Reverse Isolation	$ISO_{REV}$			49		dB
Noise Figure	NF			1.7	2.5	dB
Output Third Order Intercept Point	OIP3	$P_{OUT} = +2dBm$ / tone 1MHz tone separation	31.2	32.3		dBm
		$P_{OUT} = +2dBm$ / tone 1MHz tone separation $V_{CC} = 4.75V$ to 5.25V $T_{EPAD} = -40^\circ C$ to $+115^\circ C$	29.3			
Output 1dB Compression Point	OP1dB		21.2	22.4		dBm
		$V_{CC} = 4.75V$ to 5.25V $T_{EPAD} = -40^\circ C$ to $+115^\circ C$	19.3			

[a] Specifications in the minimum/maximum columns that are shown in **bold italics** are guaranteed by test. Specifications in these columns that are not shown in bold italics are guaranteed by design characterization.

## Electrical Characteristics – Band 3p5 (3.3GHz to 3.8GHz) / High Power Mode

See Typical Application Circuit. Specifications apply when operated as a TX amplifier with tuning optimized for the 3.3GHz to 3.8GHz band,  $V_{CC} = +5.0V$ ,  $I_{CC} = 140mA$ <sup>[a]</sup>,  $R_3 = 10k\Omega$ ,  $f_{RF} = 3.55GHz$ ,  $T_{EPAD} = +25^\circ C$ ,  $STBY = HIGH$ ,  $Z_S = Z_L = 50\Omega$ , Evaluation Kit trace and connector losses are de-embedded, unless otherwise stated.

**Table 10. Electrical Characteristics – Band 3p5 (3.3GHz to 3.8GHz) / High Power Mode**

Parameter	Symbol	Condition	Minimum	Typical	Maximum	Units
Gain	G		<b>28.0</b> <sup>[a]</sup>	29.6		dB
Gain Flatness	$G_{FLAT}$	$f_{RF} = 3.3GHz$ to 3.8GHz		0.6		dB
Gain Variation Over Temperature	$G_{TEMP}$	$T_{EPAD} = -40^\circ C$ to $+115^\circ C$ , referenced to $T_{EPAD} = 25^\circ C$		+1.2 / -1.5		dB
STBY Mode Gain	$G_{STBY}$	STBY = logic LOW $P_{IN} \leq -15dBm$ $f_{RF} = 3.3GHz$ to 3.8GHz		-40		dB
RF Input Return Loss	$RL_{RFIN}$	$f_{RF} = 3.3GHz$ to 3.8GHz		12.5		dB
RF Output Return Loss	$RL_{RFOUT}$	$f_{RF} = 3.3GHz$ to 3.8GHz		10.5		dB
Reverse Isolation	$ISO_{REV}$			49		dB
Noise Figure	NF			1.8	2.5	dB
Output Third Order Intercept Point	OIP3	$P_{OUT} = +2dBm$ / tone 1MHz tone separation	35.3	37.0		dBm
		$P_{OUT} = +2dBm$ / tone 1MHz tone separation $V_{CC} = 4.75V$ to 5.25V $T_{EPAD} = -40^\circ C$ to $+115^\circ C$	33.3			
Output 1dB Compression Point	OP1dB		22.5	24.0		dBm
		$V_{CC} = 4.75V$ to 5.25V $T_{EPAD} = -40^\circ C$ to $+115^\circ C$	21.5			

[a] Specifications in the minimum/maximum columns that are shown in **bold italics** are guaranteed by test. Specifications in these columns that are not shown in bold italics are guaranteed by design characterization.

## Electrical Characteristics – Band 4p7 (4.4GHz to 5.0GHz) / Low Power Mode

See Typical Application Circuit. Specifications apply when operated as a TX amplifier with tuning optimized for the 4.4GHz to 5.0GHz band,  $V_{CC} = +5.0V$ ,  $I_{CC} = 100mA$ ,  $R3 = 16k\Omega$ ,  $f_{RF} = 4.7GHz$ ,  $T_{EPAD} = +25^{\circ}C$ ,  $STBY = HIGH$ ,  $Z_S = Z_L = 50\Omega$ , Evaluation Kit trace and connector losses are de-embedded, unless otherwise stated.

**Table 11. Electrical Characteristics – Band 4p7 (4.4GHz to 5.0GHz) / Low Power Mode**

Parameter	Symbol	Condition	Minimum	Typical	Maximum	Units
Gain	G			27.7		dB
Gain Flatness	$G_{FLAT}$	$f_{RF} = 4.4GHz$ to $5.0GHz$		1		dB
Gain Variation Over Temperature	$G_{TEMP}$	$T_{EPAD} = -40^{\circ}C$ to $+115^{\circ}C$ , referenced to $T_{EPAD} = 25^{\circ}C$		+0.8 / -1.2		dB
STBY Mode Gain	$G_{STBY}$	STBY = logic LOW $P_{IN} \leq -15dBm$ $f_{RF} = 4.4GHz$ to $5.0GHz$		-39		dB
RF Input Return Loss	$RL_{RFIN}$	$f_{RF} = 4.4GHz$ to $5.0GHz$		7.4		dB
RF Output Return Loss	$RL_{RFOUT}$	$f_{RF} = 4.4GHz$ to $5.0GHz$		10.2		dB
Reverse Isolation	$ISO_{REV}$			50		dB
Noise Figure	NF			1.9		dB
Output Third Order Intercept Point	OIP3	$P_{OUT} = +2dBm$ / tone 1MHz tone separation		37.0		dBm
Output 1dB Compression Point	OP1dB			24.5		dBm

## Electrical Characteristics – Band 4p7 (4.4GHz to 5.0GHz) / High Power Mode

See Typical Application Circuit. Specifications apply when operated as a TX amplifier with tuning optimized for the 4.4GHz to 5.0GHz band,  $V_{CC} = +5.0V$ ,  $I_{CC} = 140mA$ ,  $R3 = 10k\Omega$ ,  $f_{RF} = 4.7GHz$ ,  $T_{EPAD} = +25^{\circ}C$ ,  $STBY = HIGH$ ,  $Z_S = Z_L = 50\Omega$ , Evaluation Kit trace and connector losses are de-embedded, unless otherwise stated.

**Table 12. Electrical Characteristics – Band 4p7 (4.4GHz to 5.0GHz) / High Power Mode**

Parameter	Symbol	Condition	Minimum	Typical	Maximum	Units
Gain	G			28.6		dB
Gain Flatness	$G_{FLAT}$	$f_{RF} = 4.4GHz$ to $5.0GHz$		1		dB
Gain Variation Over Temperature	$G_{TEMP}$	$T_{EPAD} = -40^{\circ}C$ to $+115^{\circ}C$ , referenced to $T_{EPAD} = 25^{\circ}C$		+0.8 / -1.2		dB
STBY Mode Gain	$G_{STBY}$	STBY = logic LOW $P_{IN} \leq -15dBm$ $f_{RF} = 4.4GHz$ to $5.0GHz$		-39		dB
RF Input Return Loss	$RL_{RFIN}$	$f_{RF} = 4.4GHz$ to $5.0GHz$		8.2		dB
RF Output Return Loss	$RL_{RFOUT}$	$f_{RF} = 4.4GHz$ to $5.0GHz$		11		dB
Reverse Isolation	$ISO_{REV}$			50		dB
Noise Figure	NF			1.9		dB
Output Third Order Intercept Point	OIP3	$P_{OUT} = +2dBm$ / tone 1MHz tone separation		42.1		dBm
Output 1dB Compression Point	OP1dB			25.1		dBm

## Thermal Characteristics

**Table 13. Package Thermal Characteristics**

Parameter	Symbol	Value	Units
Junction to Ambient Thermal Resistance	$\theta_{JA}$	67.9	°C/W
Junction to Case Thermal Resistance. (Case is defined as the exposed paddle)	$\theta_{JC\_BOT}$	22.9	°C/W
Moisture Sensitivity Rating (Per J-STD-020)		MSL 3	

## Typical Operating Conditions

Unless otherwise stated the typical operating graphs were measured under the following conditions:

- $V_{CC} = 5.0V$
- $Z_S = Z_L = 50\Omega$  Single Ended
- $I_{CC} = 100mA$  or  $140mA$
- $f_{RF} = 2.0GHz$  (Band 2p0)
- $f_{RF} = 2.5GHz$  (Band 2p5)
- $f_{RF} = 3.55GHz$  (Band 3p5)
- $f_{RF} = 4.7GHz$  (Band 4p7)
- $T_{EPAD} = +25^\circ C$
- STBY = HIGH
- 1MHz Tone Spacing
- All temperatures are referenced to the exposed paddle

## Typical Performance Characteristics (Band 2p0 – 1.8GHz to 2.2GHz)

Figure 3. Gain - Low Power Mode

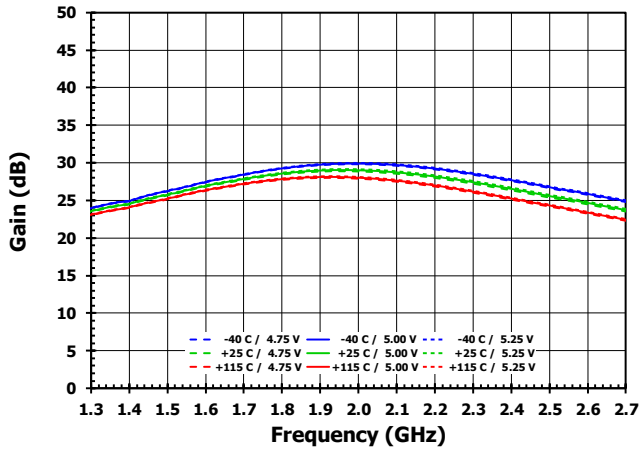


Figure 4. Gain - High Power Mode

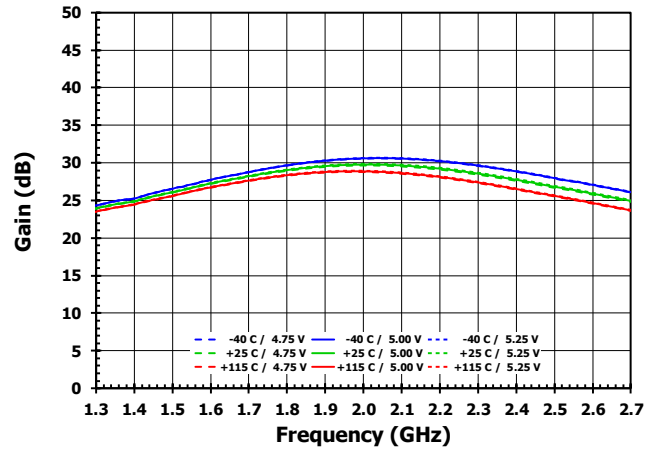


Figure 5. Input Return Loss - Low Power Mode

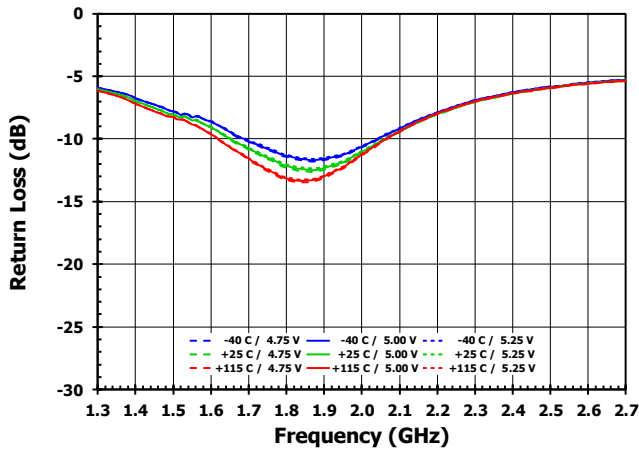


Figure 6. Input Return Loss - High Power Mode

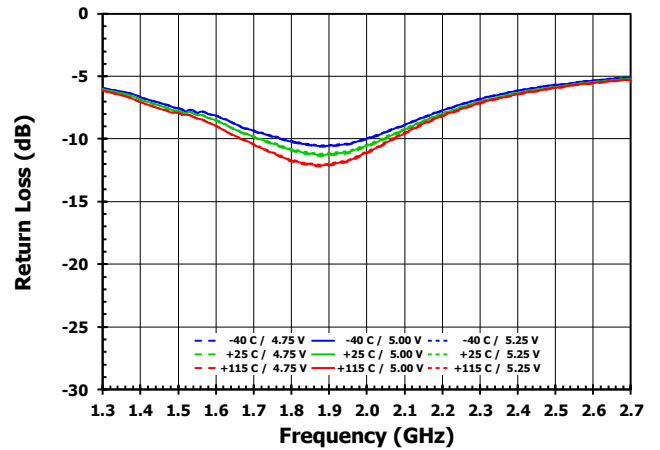


Figure 7. Output Return Loss - Low Power Mode

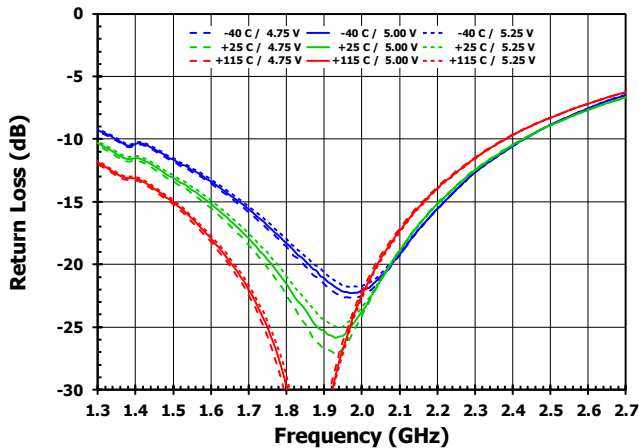
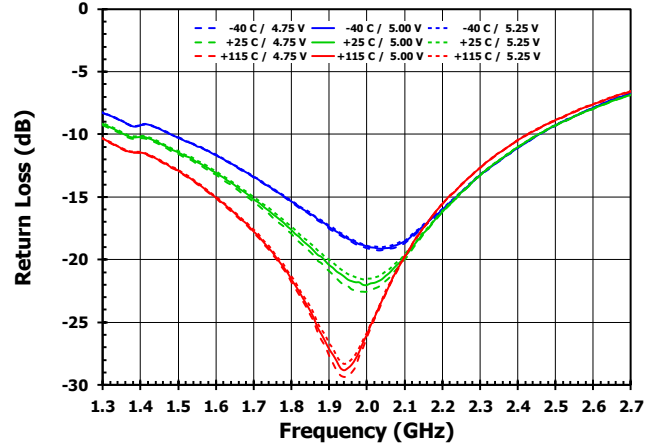


Figure 8. Output Return Loss - High Power Mode



## Typical Performance Characteristics (Band 2p0 – 1.8GHz to 2.2GHz)

Figure 9. Gain - Low Power Mode, Broadband

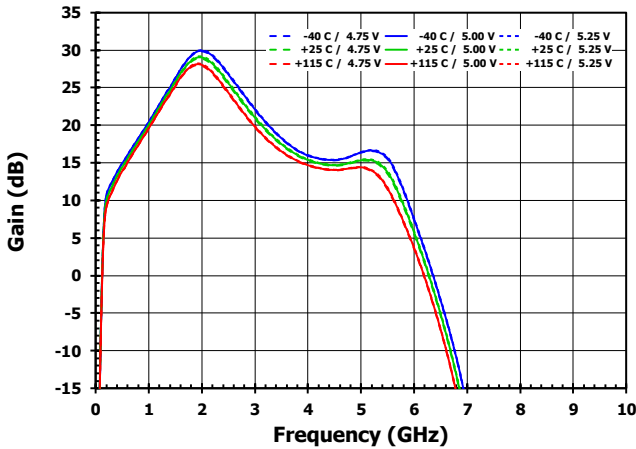


Figure 10. Gain - High Power Mode, Broadband

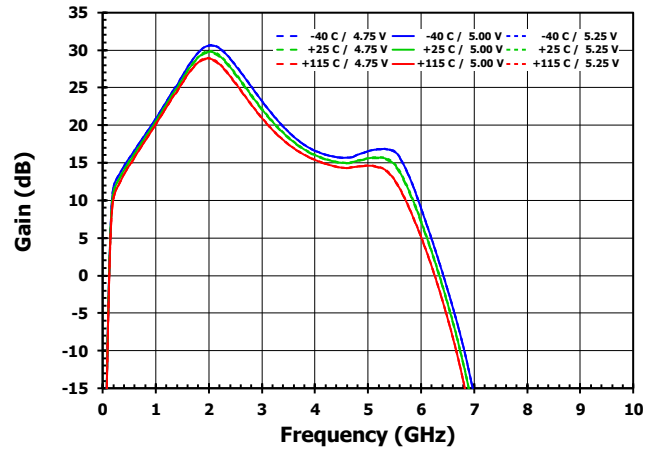


Figure 11. Input Return Loss - Low Power Mode, Broadband

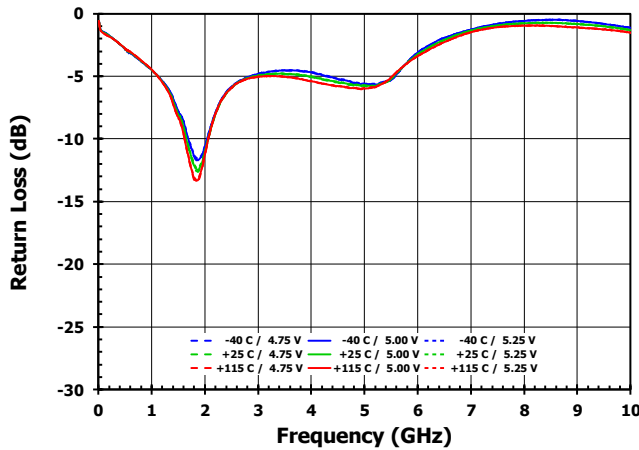


Figure 12. Input Return Loss - High Power Mode, Broadband

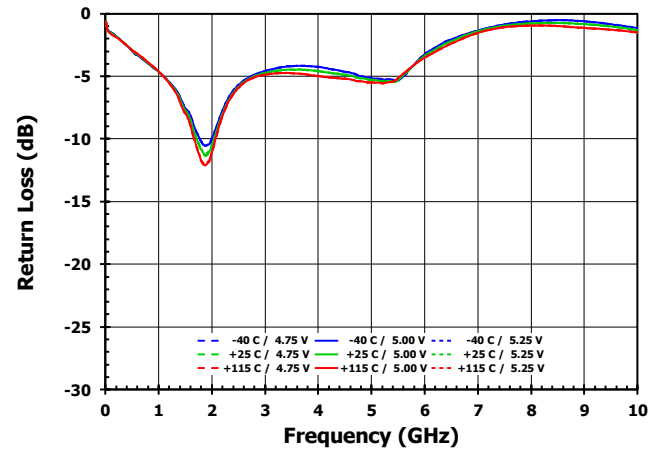


Figure 13. Output Return Loss - Low Power Mode, Broadband

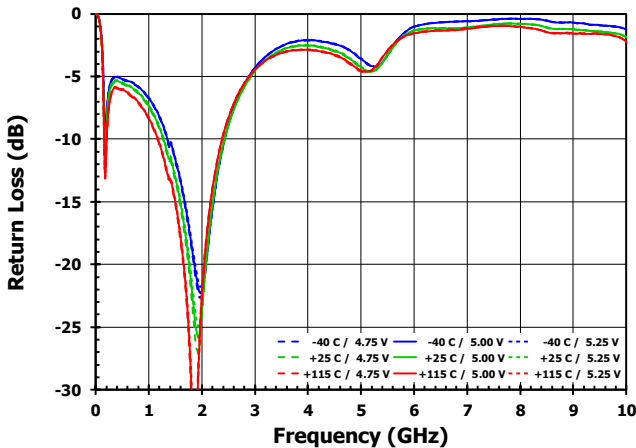
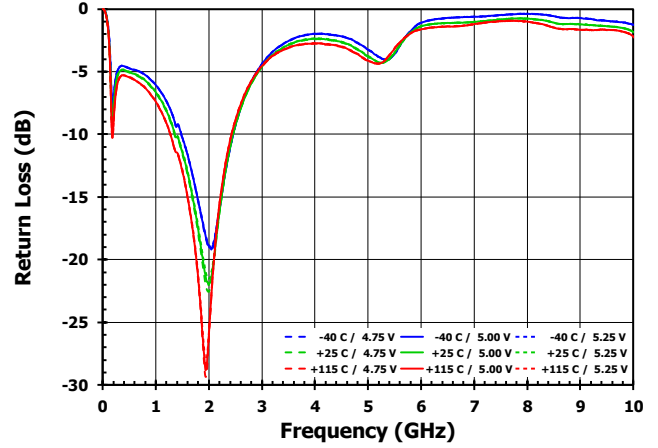


Figure 14. Output Return Loss - High Power Mode, Broadband



## Typical Performance Characteristics (Band 2p0 – 1.8GHz to 2.2GHz)

Figure 15. Reverse Isolation - Low Power Mode

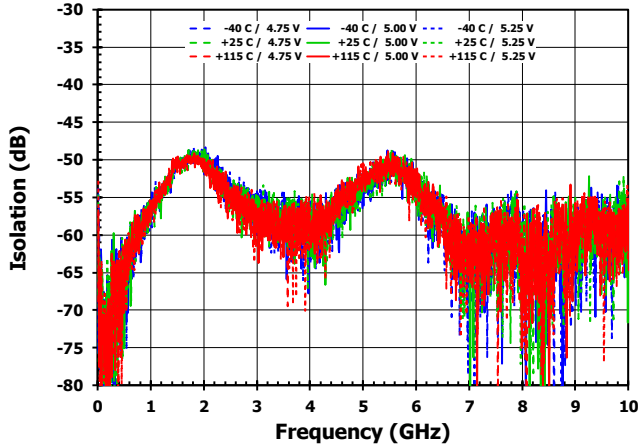


Figure 16. Reverse Isolation - High Power Mode

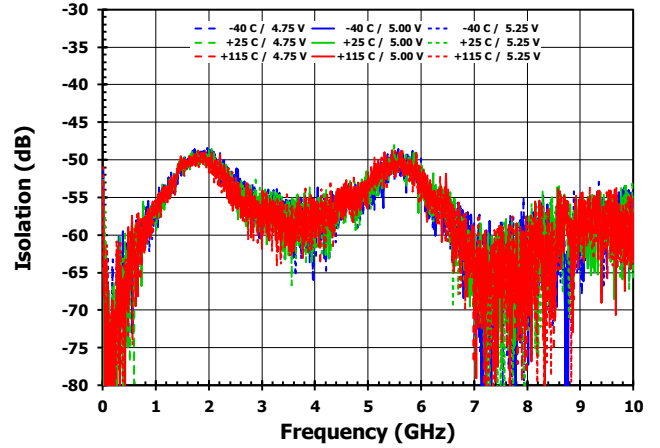


Figure 17. Standby Mode Gain

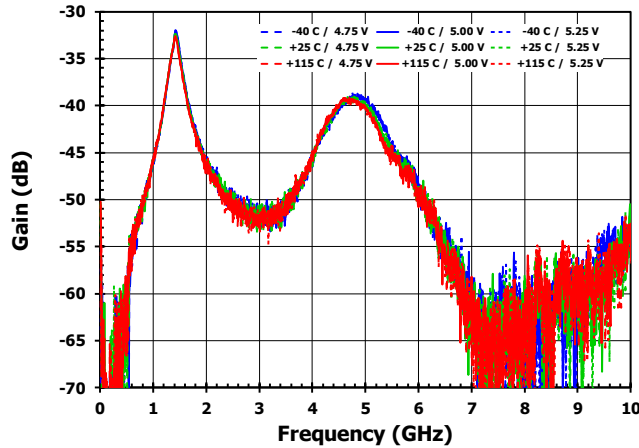


Figure 18. Current versus Power Supply Voltage

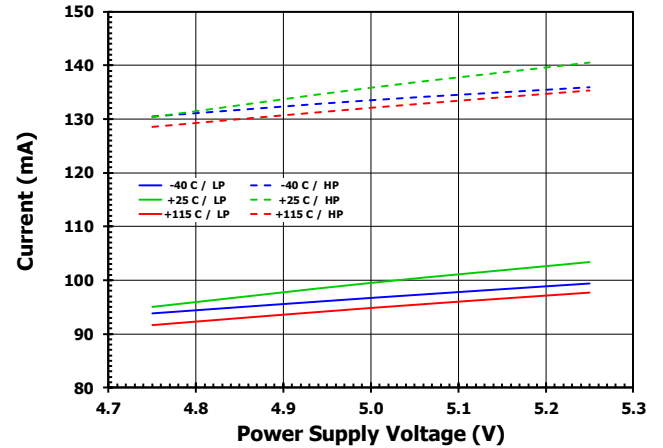


Figure 19. Standby Mode Reverse Isolation

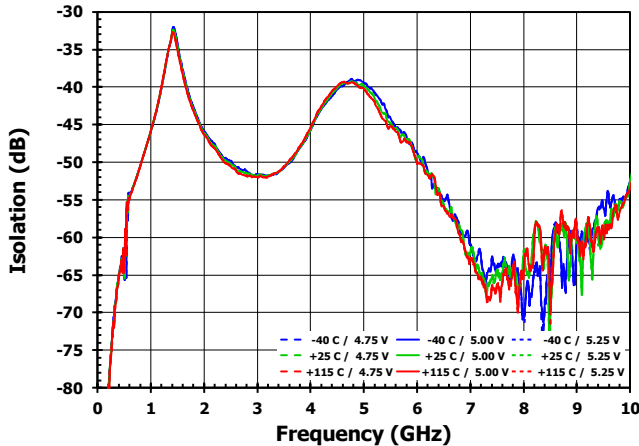
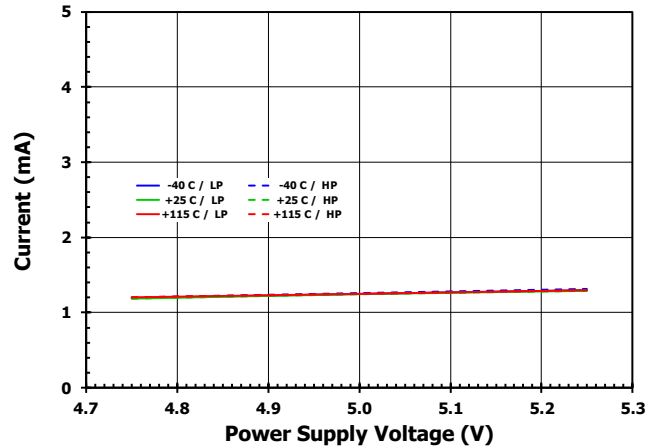


Figure 20. Standby Current versus Power Supply Voltage



## Typical Performance Characteristics (Band 2p0 – 1.8GHz to 2.2GHz)

Figure 21. Output IP3 - Low Power Mode

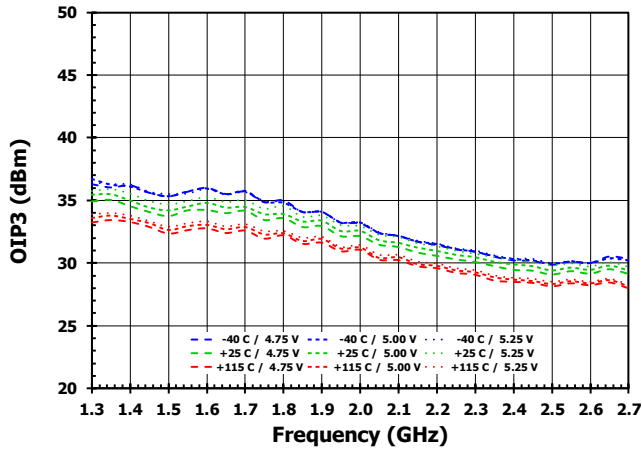


Figure 22. Output IP3 - High Power Mode

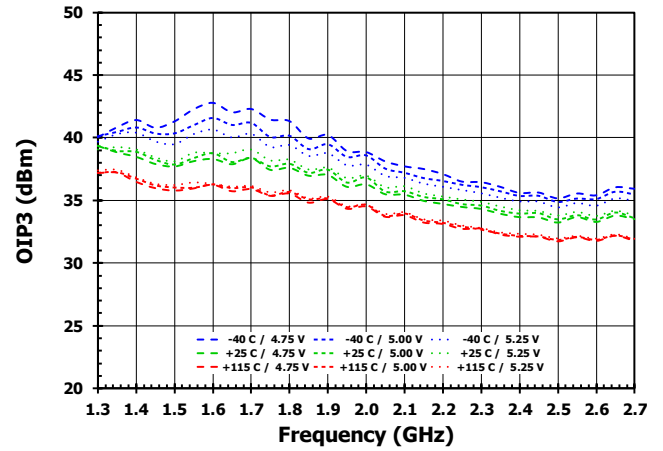


Figure 23. Output Compression - Low Power Mode

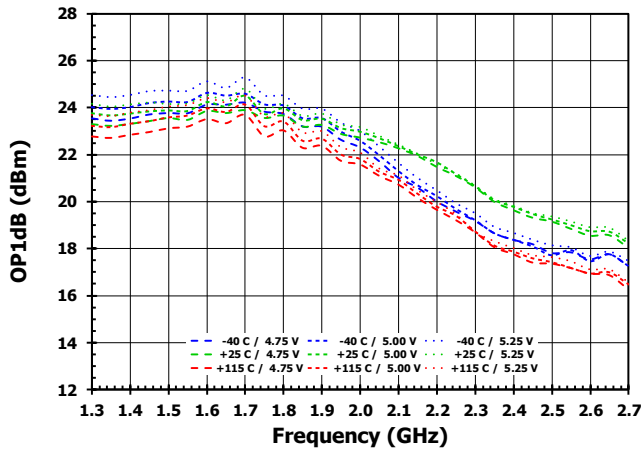


Figure 24. Output Compression - High Power Mode

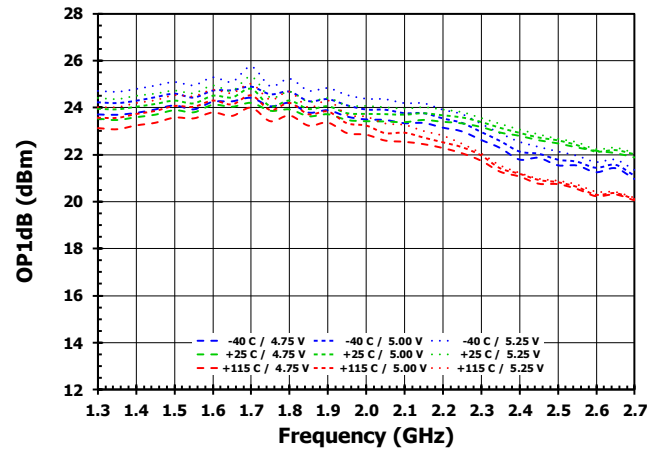


Figure 25. Noise Figure - Low Power Mode

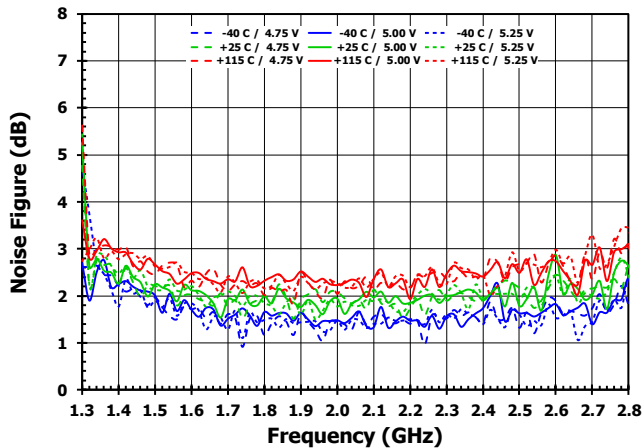
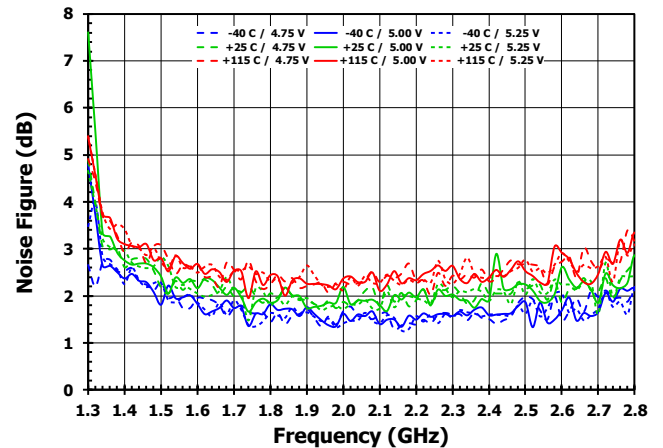


Figure 26. Noise Figure - High Power Mode



## Typical Performance Characteristics (Band 2p5 – 2.3GHz to 2.7GHz)

Figure 27. Gain - Low Power Mode

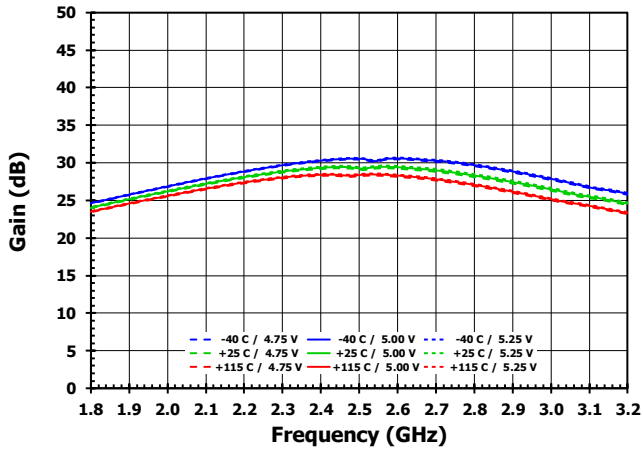


Figure 29. Input Return Loss - Low Power Mode

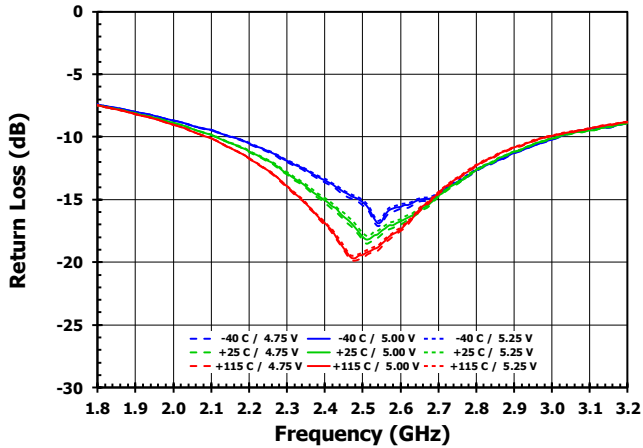


Figure 31. Output Return Loss - Low Power Mode

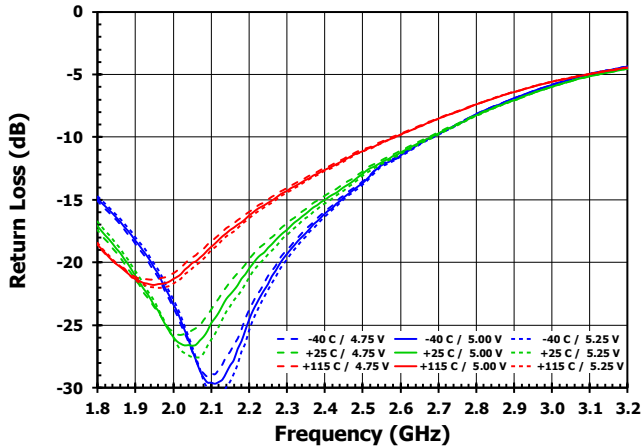


Figure 28. Gain - High Power Mode

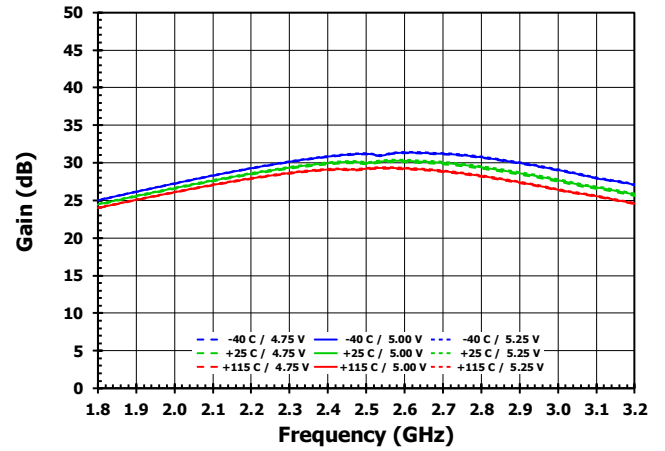


Figure 30. Input Return Loss - High Power Mode

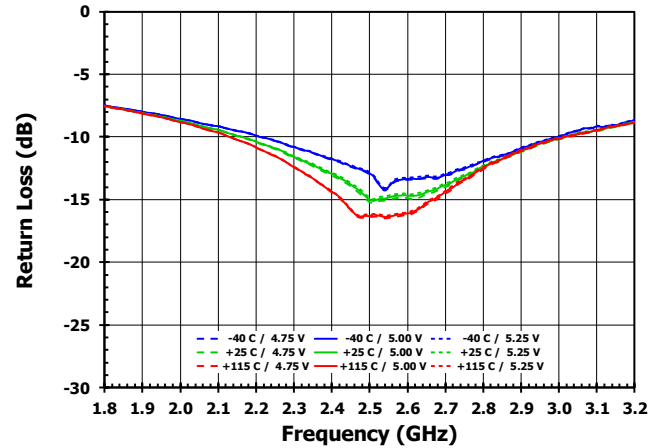
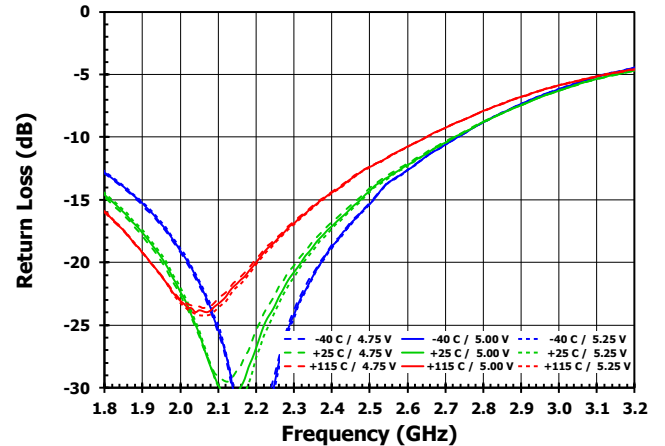


Figure 32. Output Return Loss - High Power Mode



## Typical Performance Characteristics (Band 2p5 – 2.3GHz to 2.7GHz)

Figure 33. Gain - Low Power Mode, Broadband

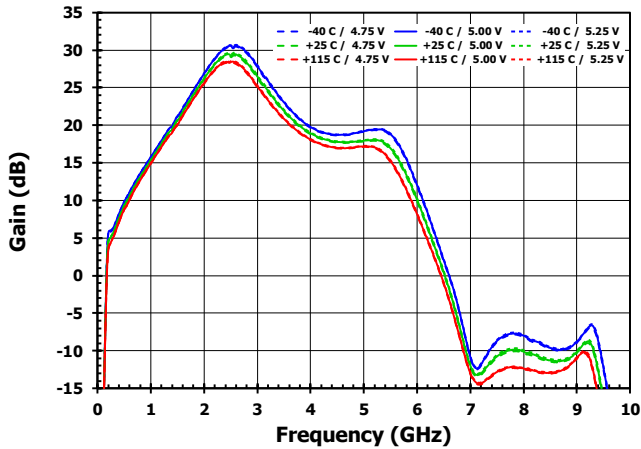


Figure 34. Gain - High Power Mode, Broadband

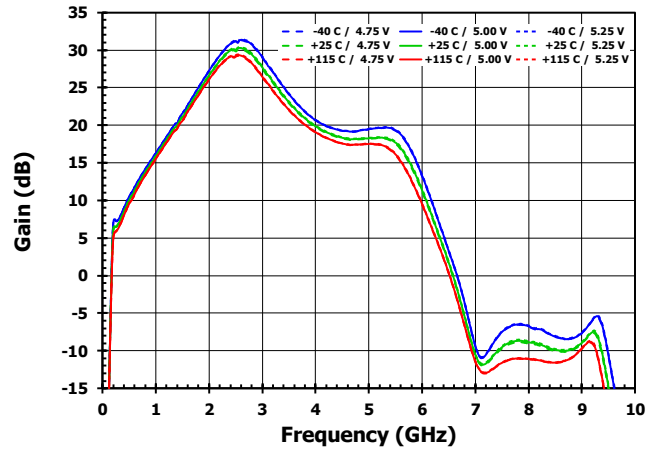


Figure 35. Input Return Loss - Low Power Mode, Broadband

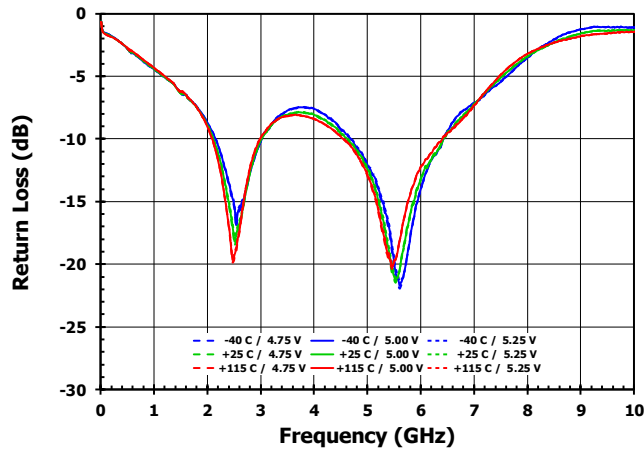


Figure 36. Input Return Loss - High Power Mode, Broadband

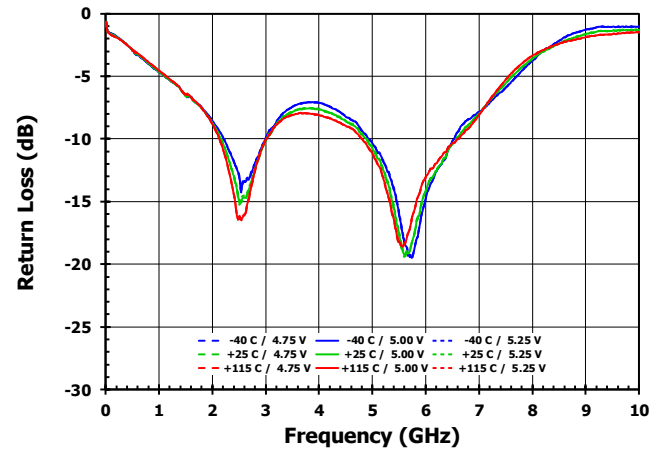


Figure 37. Output Return Loss - Low Power Mode, Broadband

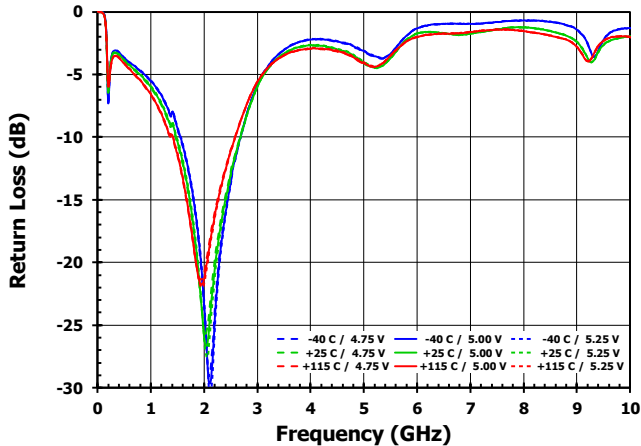
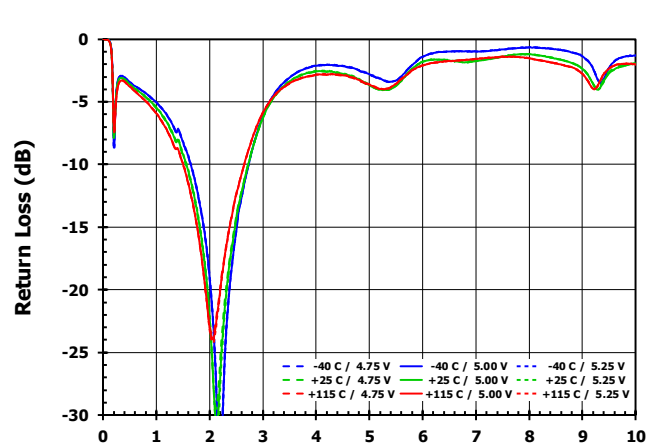


Figure 38. Output Return Loss - High Power Mode, Broadband



## Typical Performance Characteristics (Band 2p5 – 2.3GHz to 2.7GHz)

Figure 39. Reverse Isolation - Low Power Mode

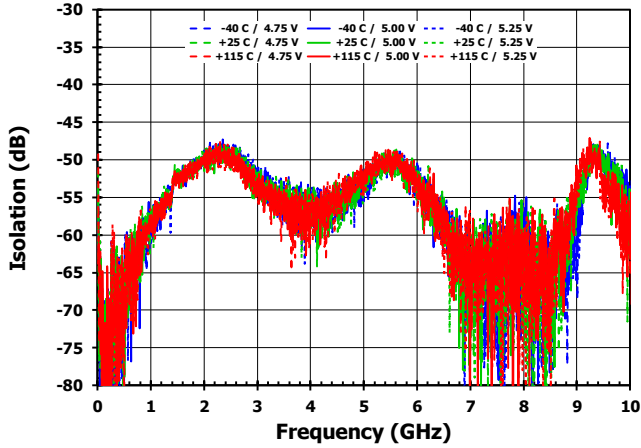


Figure 40. Reverse Isolation - High Power Mode

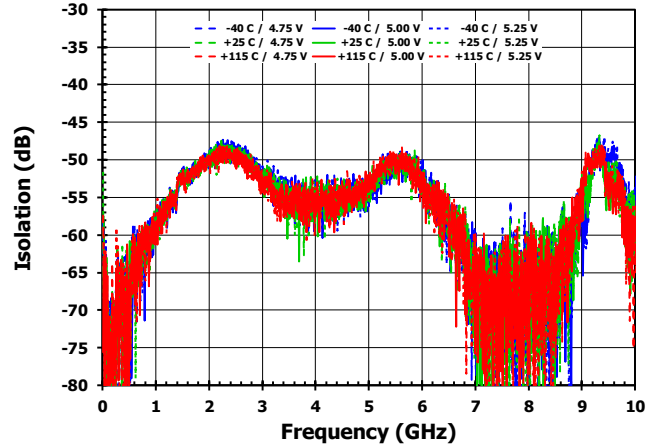


Figure 41. Standby Mode Gain

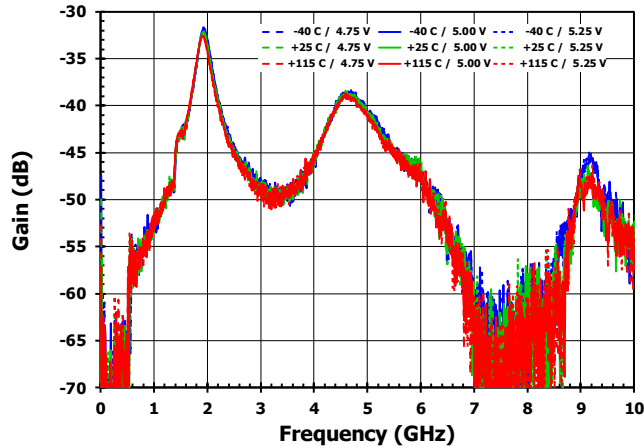


Figure 42. Current versus Power Supply Voltage

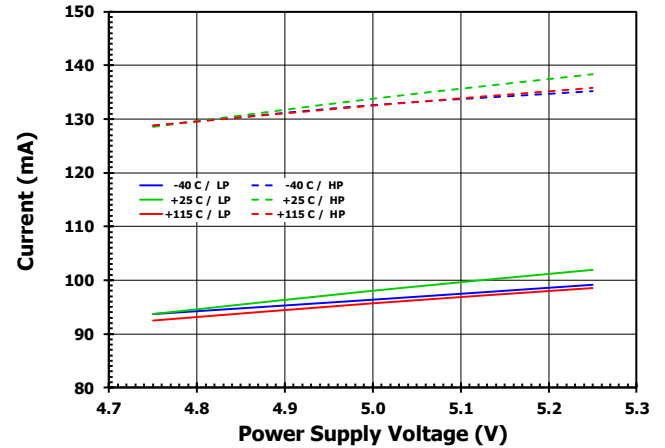


Figure 43. Standby Mode Reverse Isolation

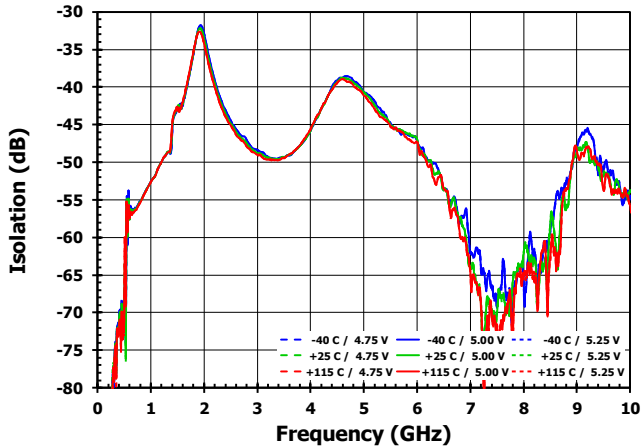
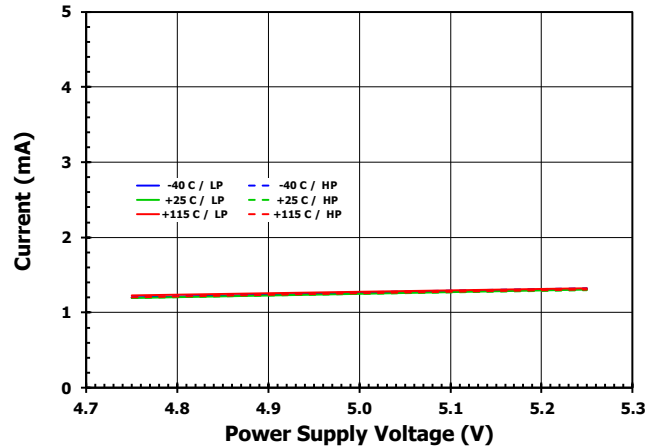


Figure 44. Standby Current versus Power Supply Voltage



## Typical Performance Characteristics (Band 2p5 – 2.3GHz to 2.7GHz)

Figure 45. Output IP3 - Low Power Mode

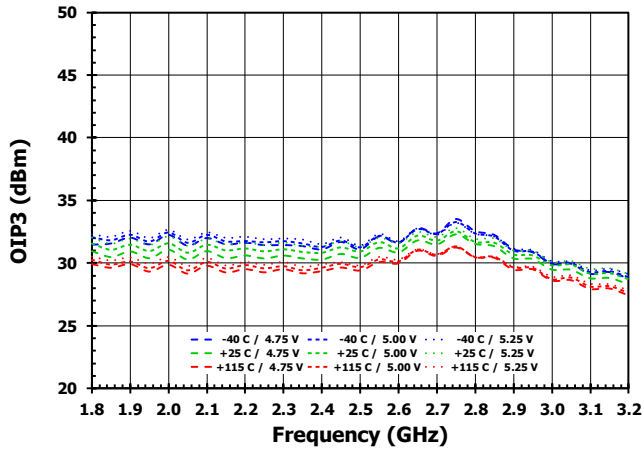


Figure 46. Output IP3 - High Power Mode

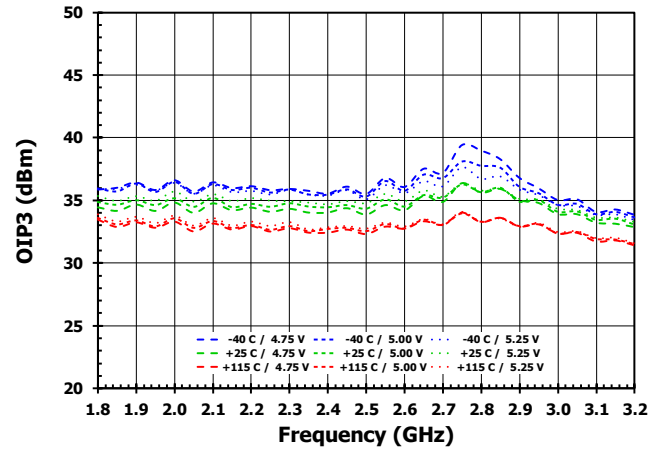


Figure 47. Output Compression - Low Power Mode

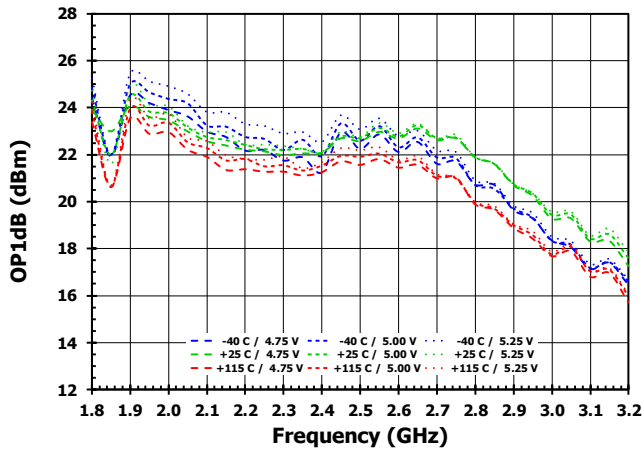


Figure 48. Output Compression - High Power Mode

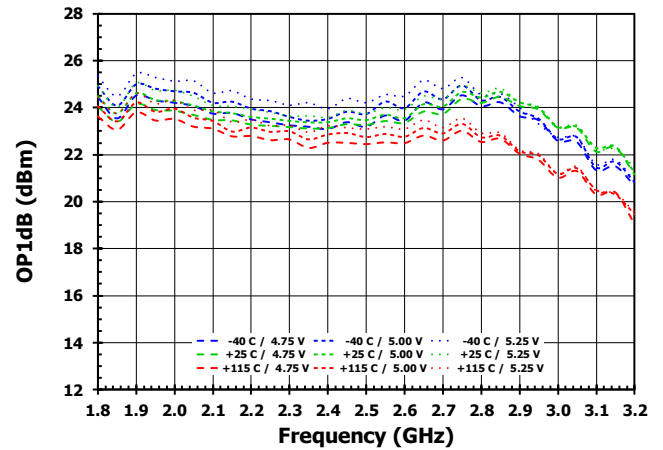


Figure 49. Noise Figure - Low Power Mode

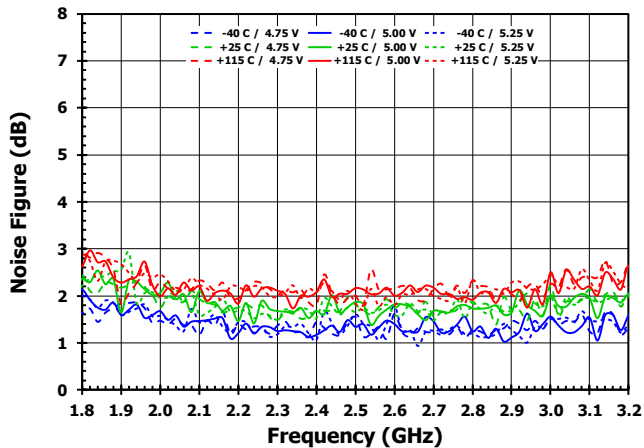
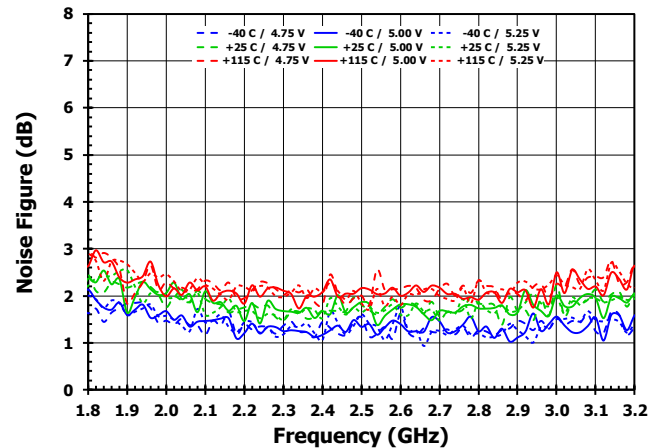


Figure 50. Noise Figure - High Power Mode



## Typical Performance Characteristics (Band 3p5 – 3.3GHz to 3.8GHz)

Figure 51. Gain - Low Power Mode

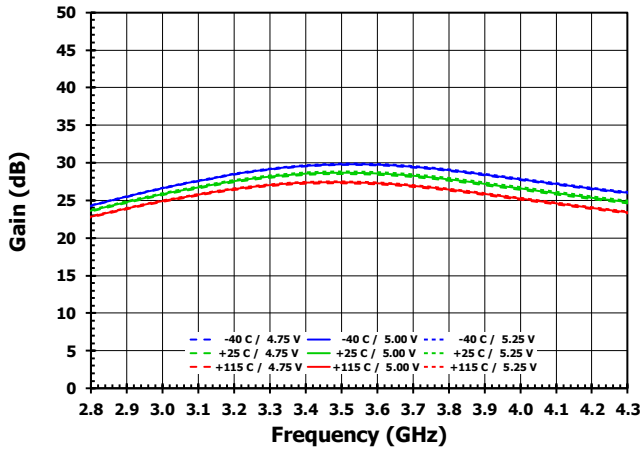


Figure 52. Gain - High Power Mode

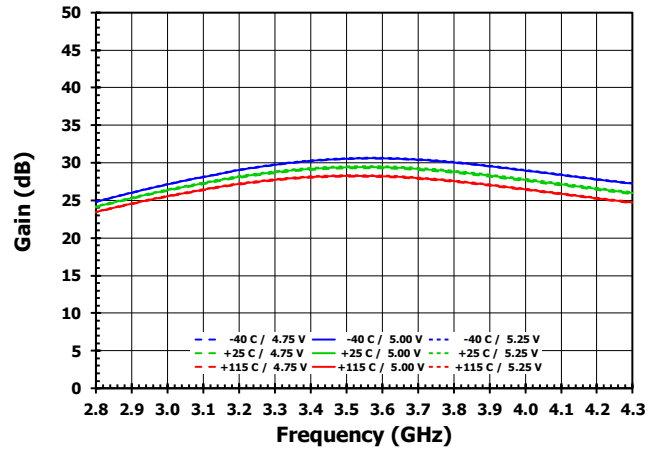


Figure 53. Input Return Loss - Low Power Mode

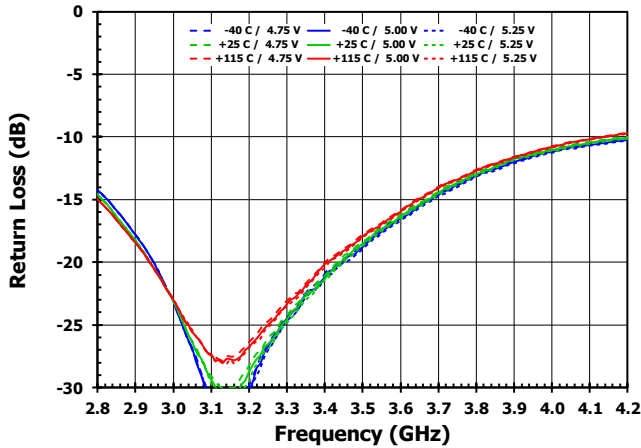


Figure 54. Input Return Loss - High Power Mode

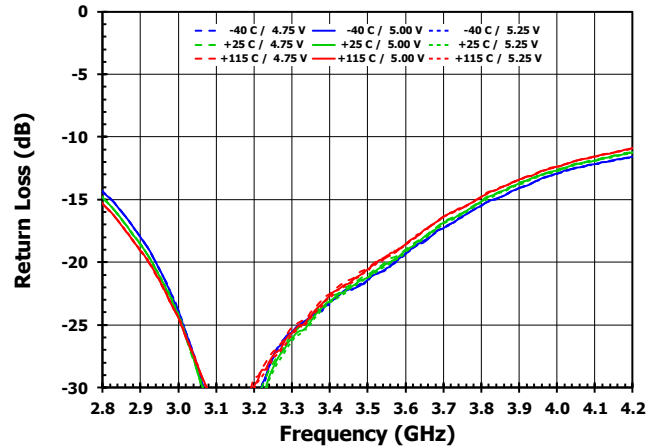


Figure 55. Output Return Loss - Low Power Mode

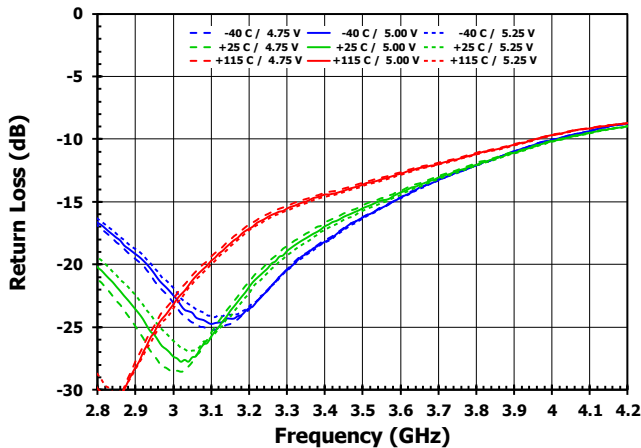
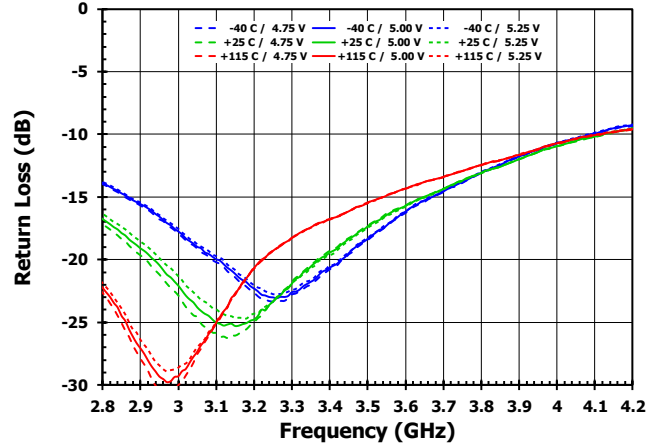


Figure 56. Output Return Loss - High Power Mode



## Typical Performance Characteristics (Band 3p5 – 3.3GHz to 3.8GHz)

Figure 57. Gain - Low Power Mode, Broadband

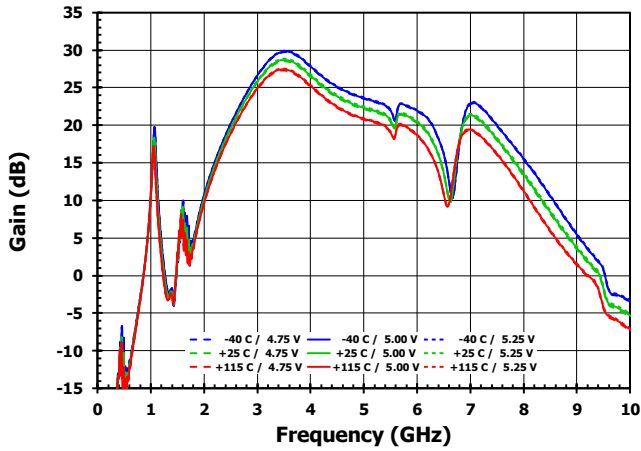


Figure 58. Gain - High Power Mode, Broadband

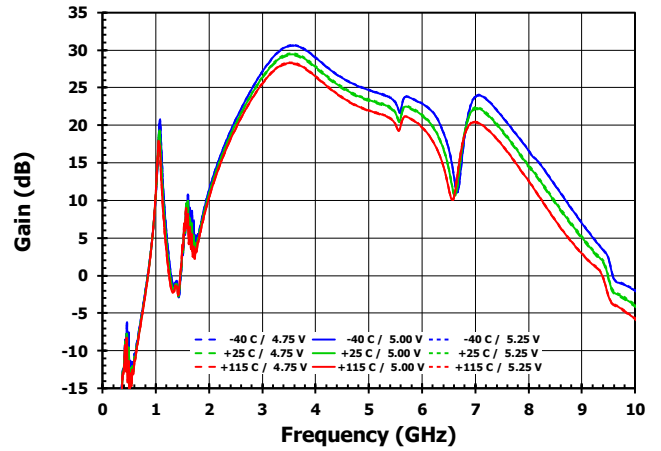


Figure 59. Input Return Loss - Low Power Mode, Broadband

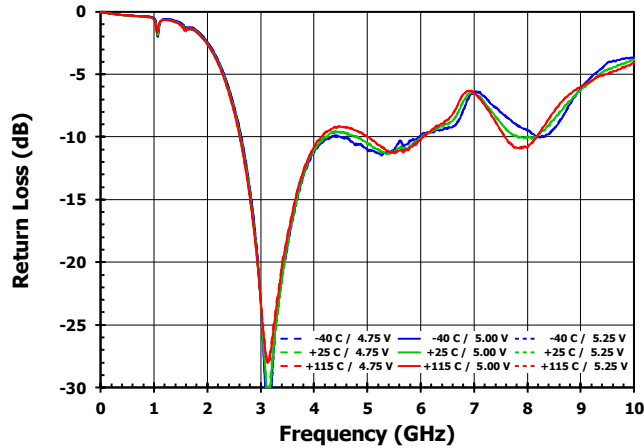


Figure 60. Input Return Loss - High Power Mode, Broadband

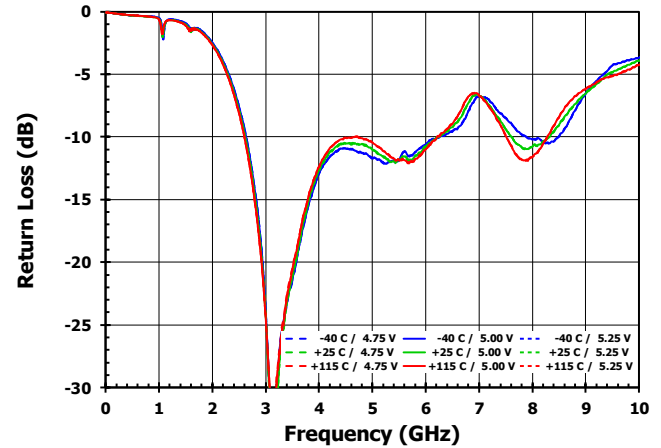


Figure 61. Output Return Loss - Low Power Mode, Broadband

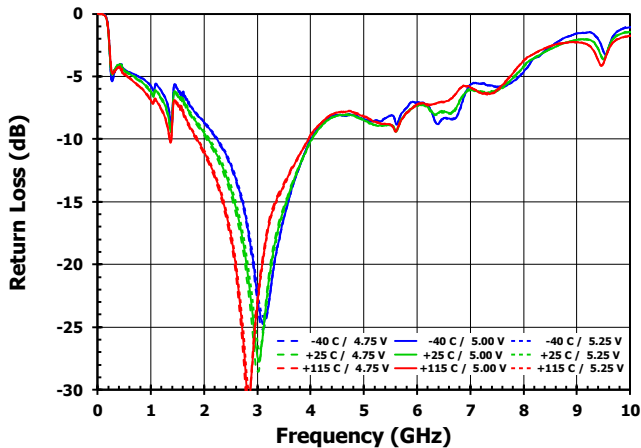
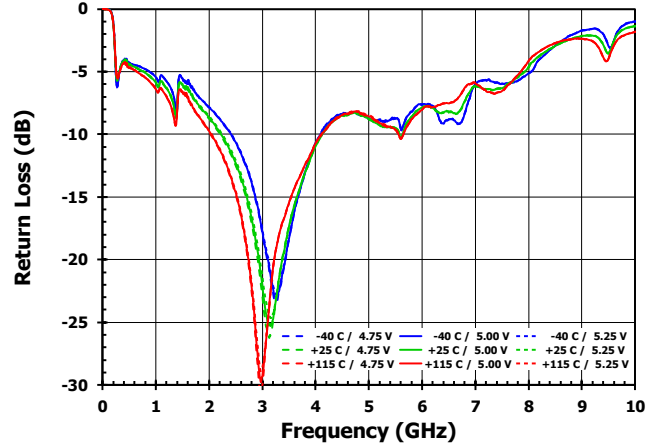


Figure 62. Output Return Loss - High Power Mode, Broadband



## Typical Performance Characteristics (Band 3p5 – 3.3GHz to 3.8GHz)

Figure 63. Reverse Isolation - Low Power Mode

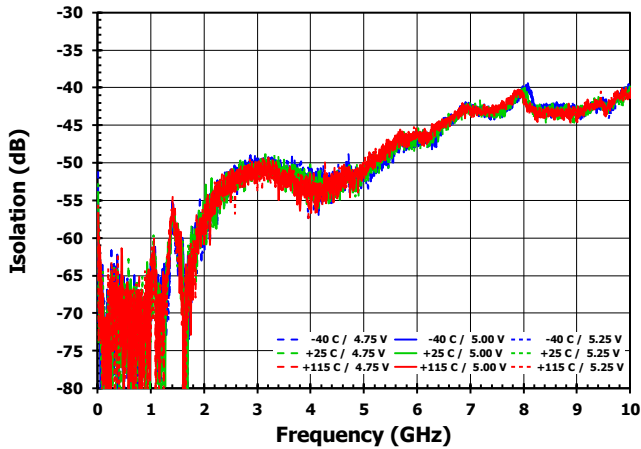


Figure 64. Reverse Isolation - High Power Mode

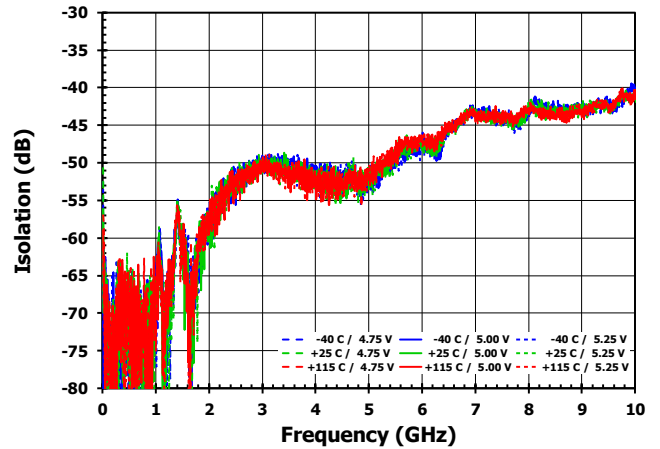


Figure 65. Standby Mode Gain versus Frequency

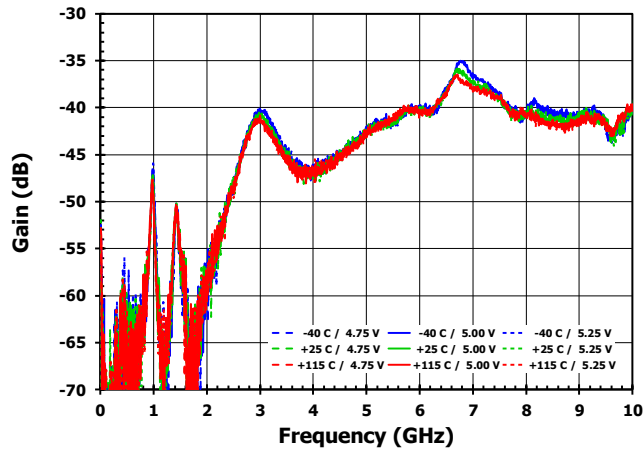


Figure 66. Current versus Power Supply Voltage

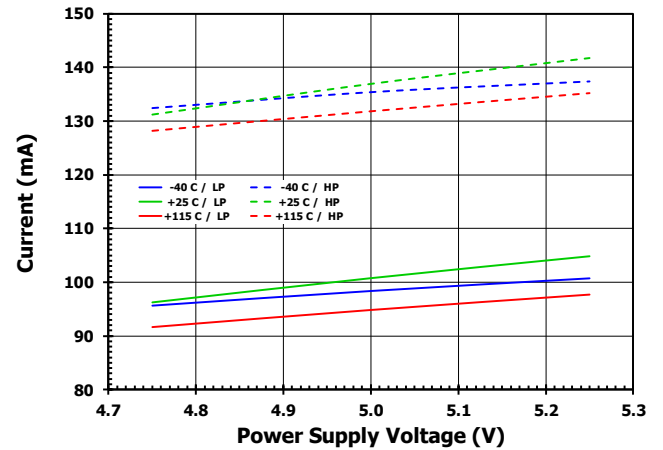


Figure 67. Standby Mode Reverse Isolation

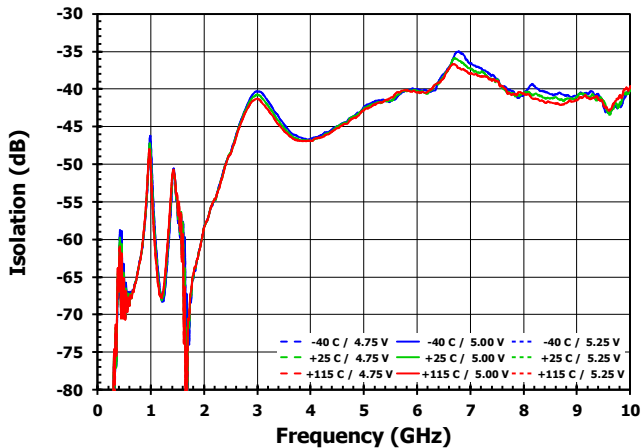
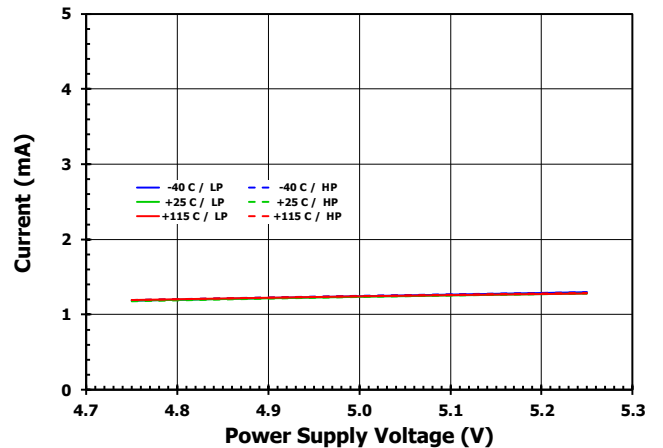


Figure 68. Standby Current versus Power Supply Voltage



## Typical Performance Characteristics (Band 3p5 – 3.3GHz to 3.8GHz)

Figure 69. Output IP3 - Low Power Mode

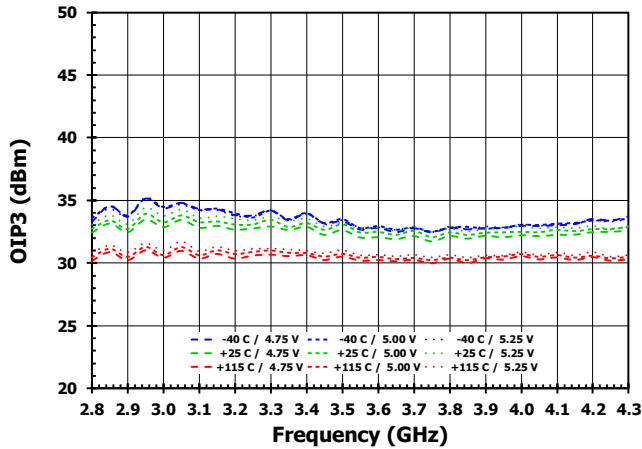


Figure 70. Output IP3 - High Power Mode

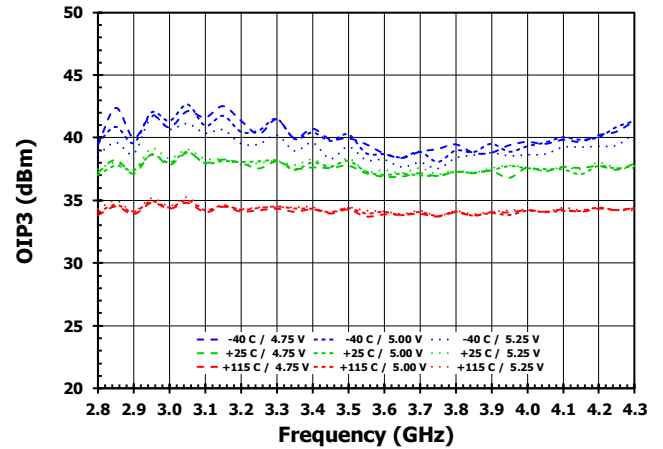


Figure 71. Output Compression - Low Power Mode

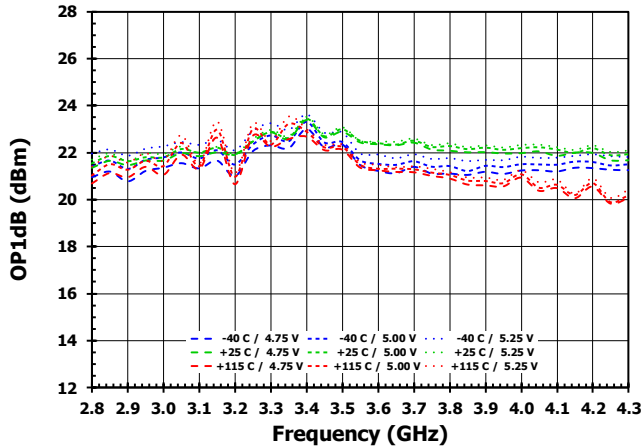


Figure 72. Output Compression - High Power Mode

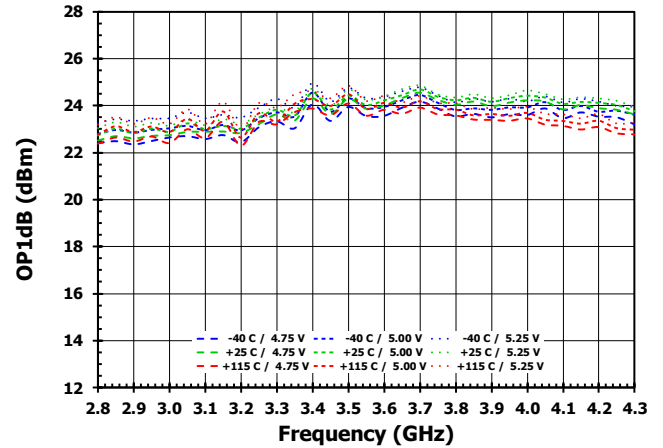


Figure 73. Noise Figure - Low Power Mode

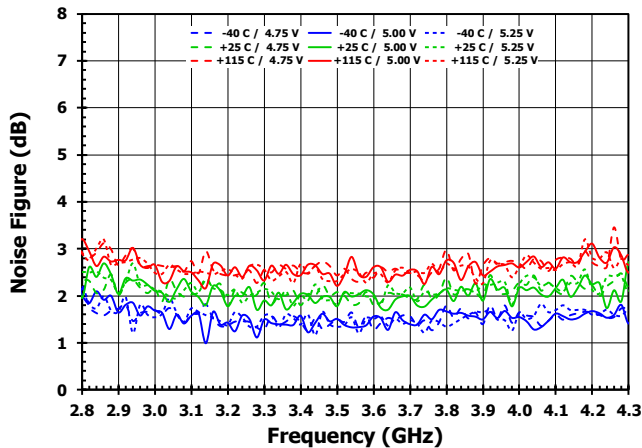
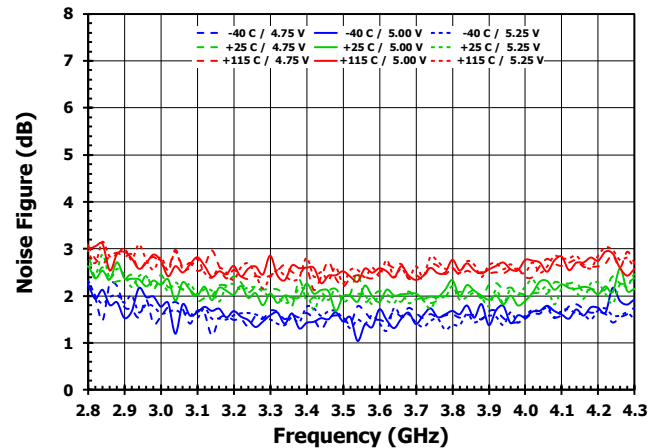


Figure 74. Noise Figure - High Power Mode



## Typical Performance Characteristics (Band 4p7 – 4.4GHz to 5.0GHz)

Figure 75. Gain - Low Power Mode

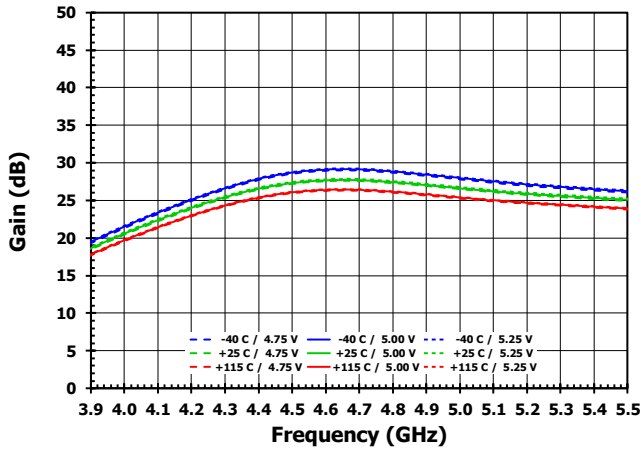


Figure 76. Gain - High Power Mode

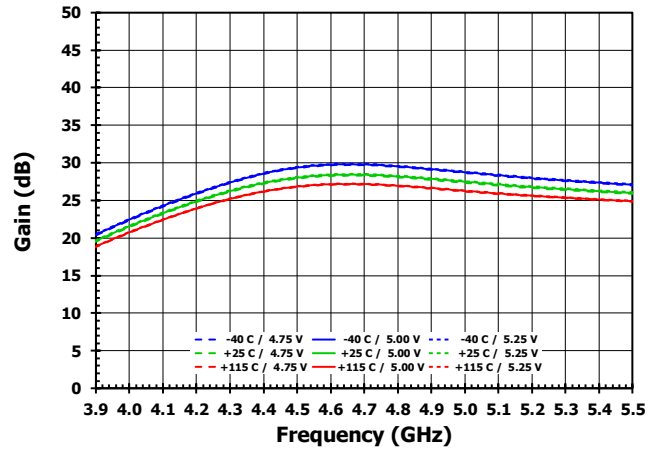


Figure 77. Input Return Loss - Low Power Mode

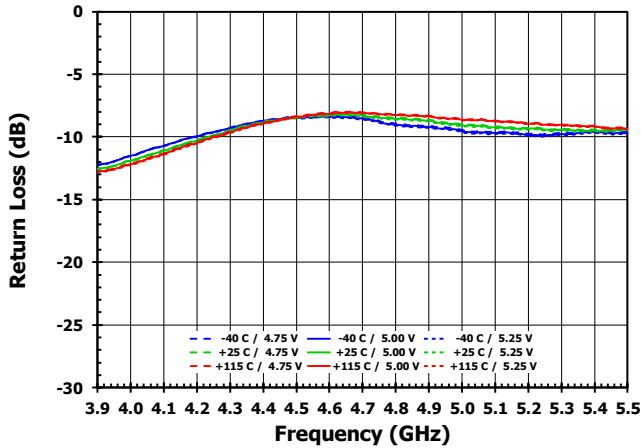


Figure 78. Input Return Loss - High Power Mode

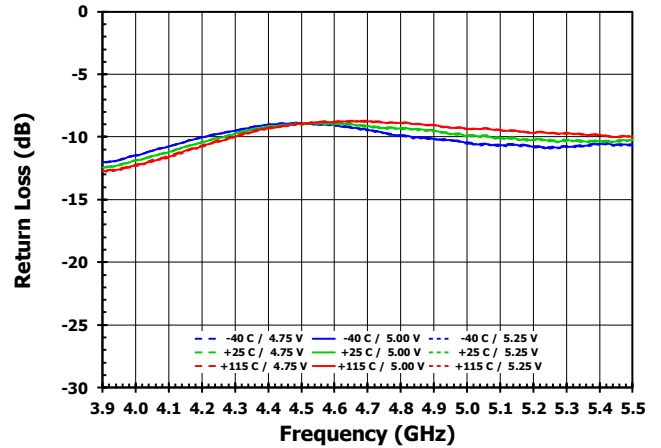


Figure 79. Output Return Loss - Low Power Mode

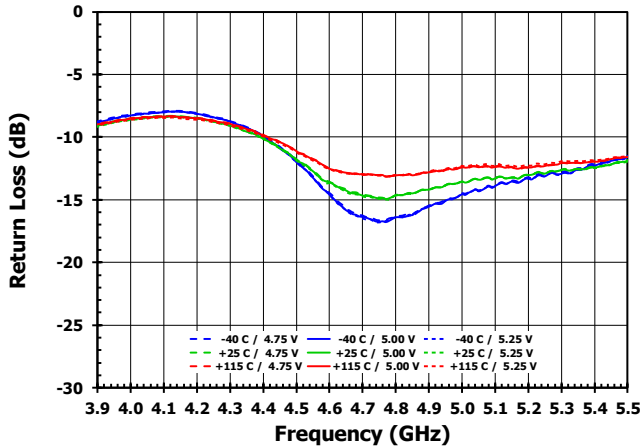
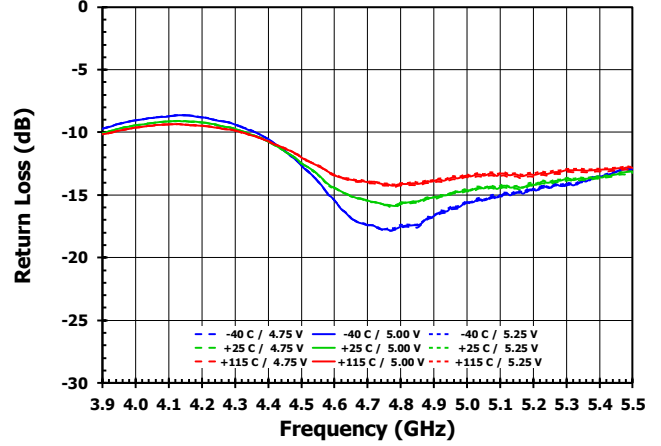


Figure 80. Output Return Loss - High Power Mode



## Typical Performance Characteristics (Band 4p7 – 4.4GHz to 5.0GHz)

Figure 81. Gain - Low Power Mode, Broadband

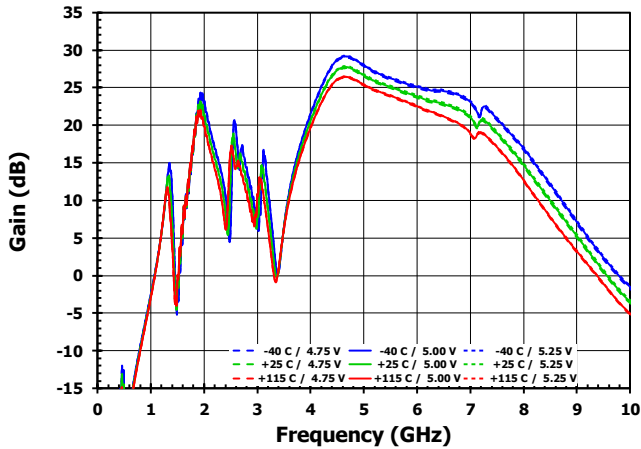


Figure 82. Gain - High Power Mode, Broadband

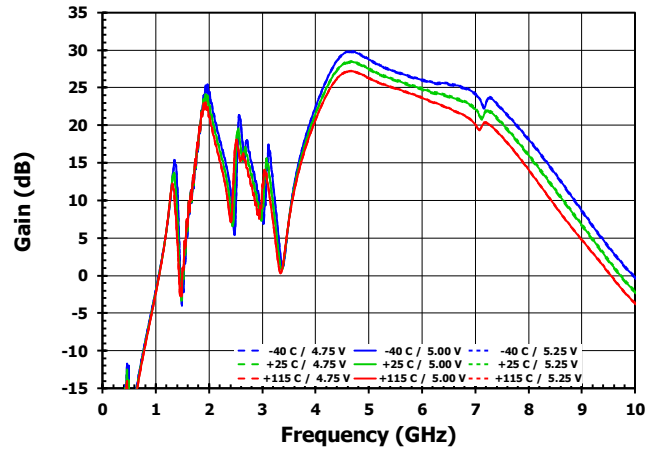


Figure 83. Input Return Loss - Low Power Mode, Broadband

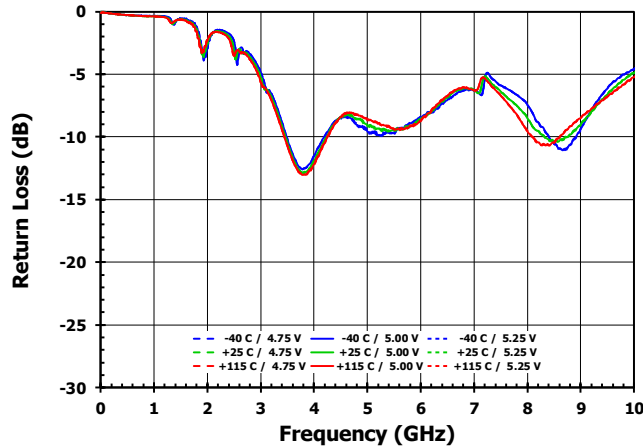


Figure 84. Input Return Loss - High Power Mode, Broadband

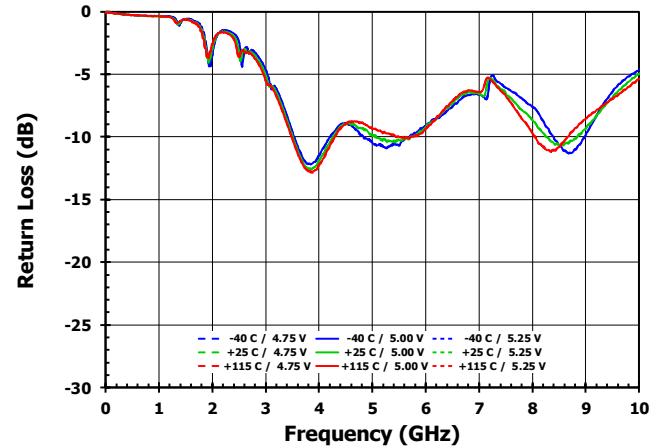


Figure 85. Output Return Loss - Low Power Mode, Broadband

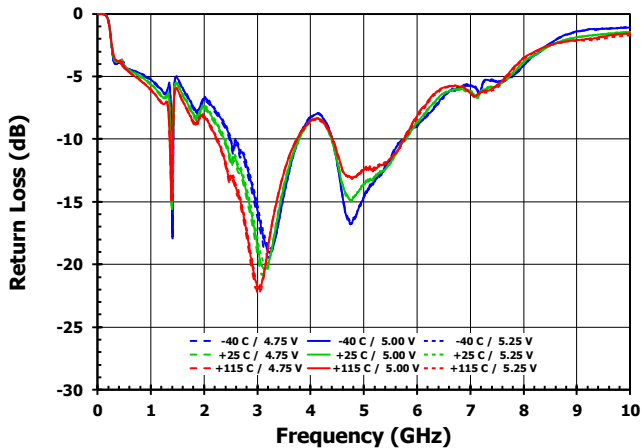
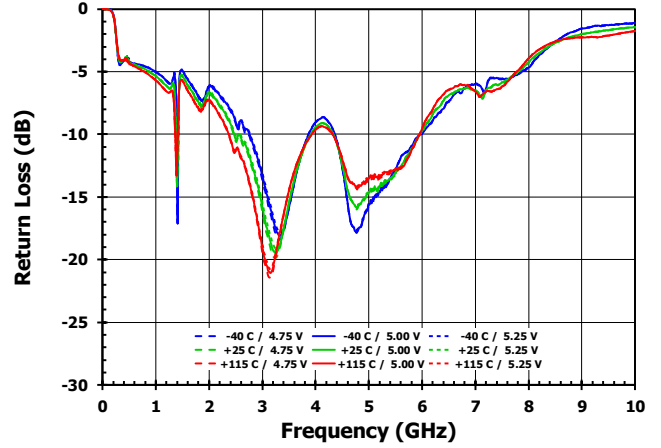


Figure 86. Output Return Loss - High Power Mode, Broadband



## Typical Performance Characteristics (Band 4p7 – 4.4GHz to 5.0GHz)

Figure 87. Reverse Isolation - Low Power Mode

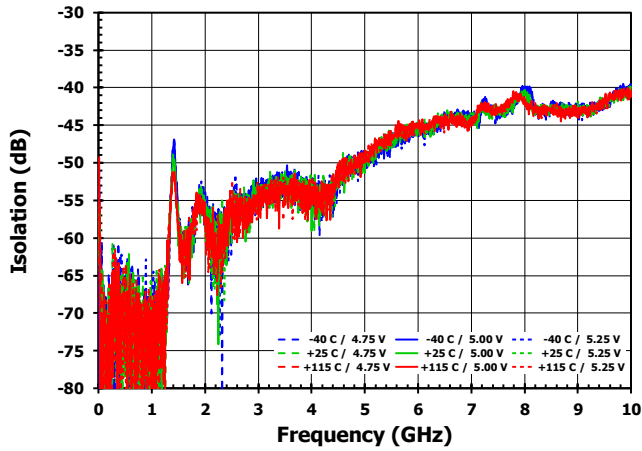


Figure 88. Reverse Isolation - High Power Mode

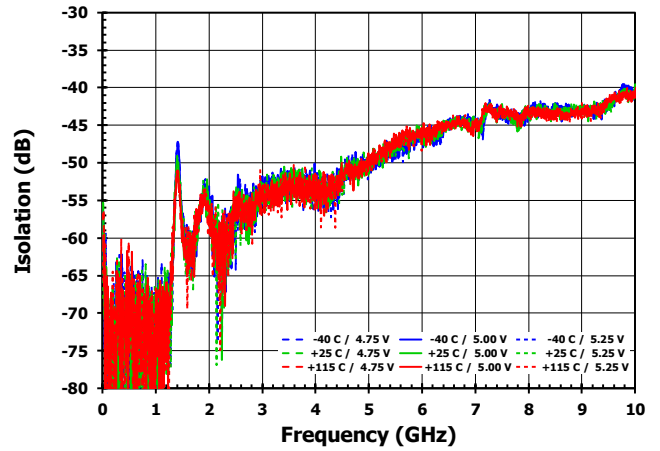


Figure 89. Standby Mode Gain

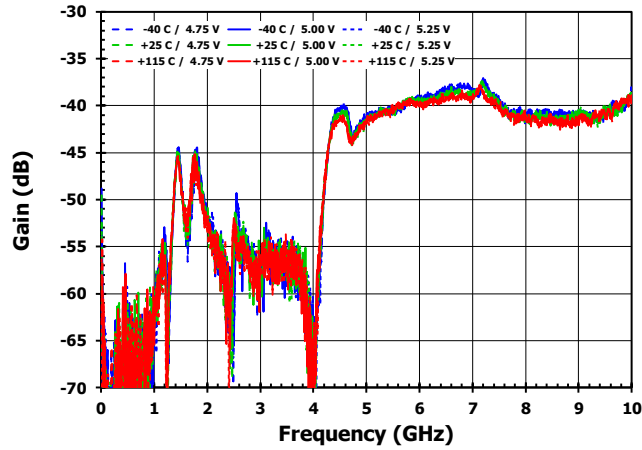


Figure 90. Current versus Power Supply Voltage

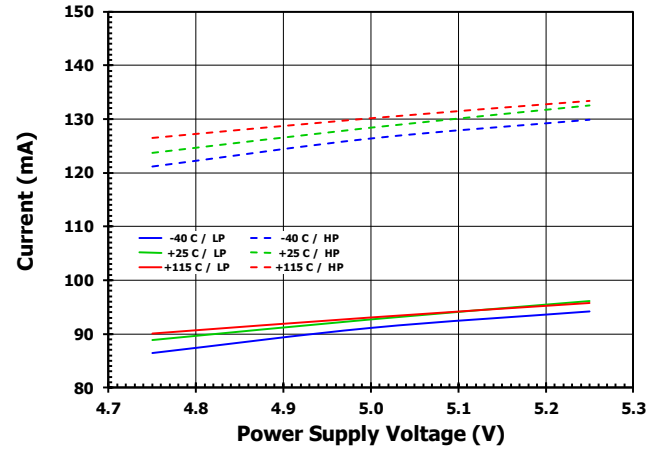


Figure 91. Standby Mode Reverse Isolation

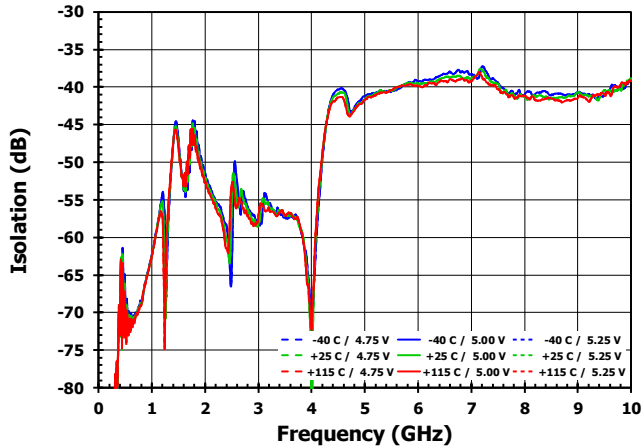
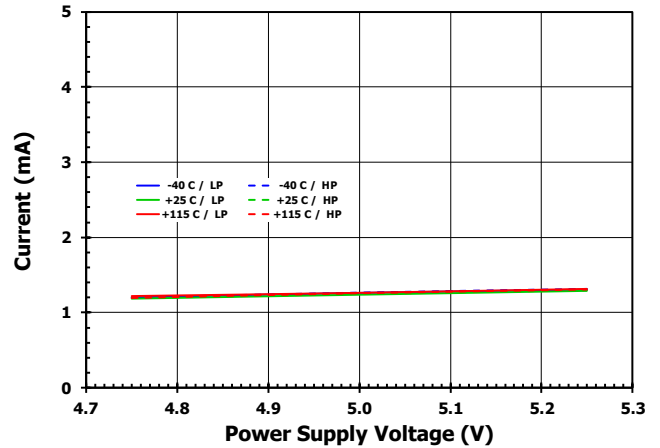


Figure 92. Standby Current versus Power Supply Voltage



## Typical Performance Characteristics (Band 4p7 – 4.4GHz to 5.0GHz)

Figure 93. Output IP3 - Low Power Mode

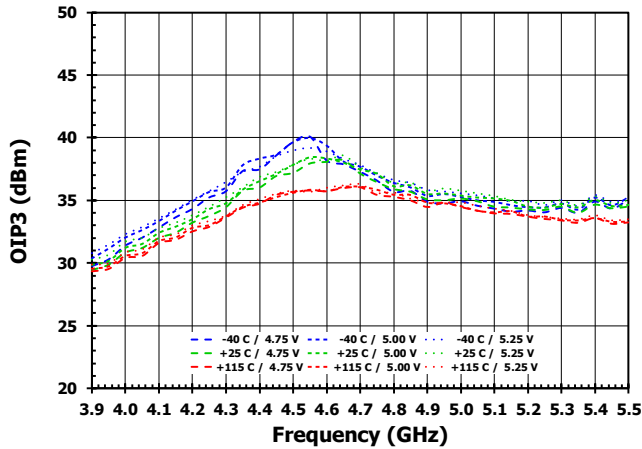


Figure 94. Output IP3 - High Power Mode

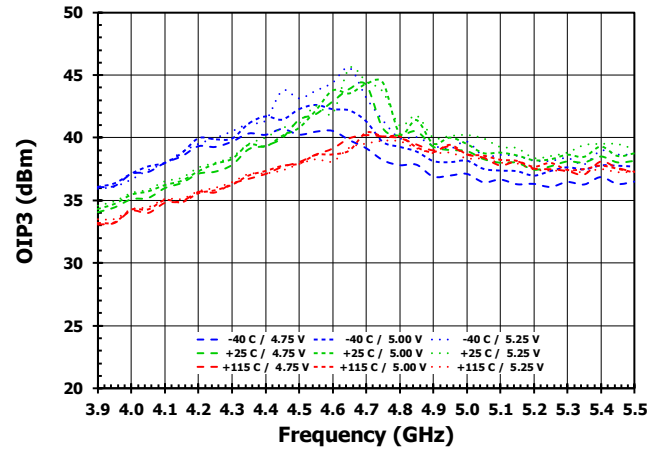


Figure 95. Output Compression - Low Power Mode

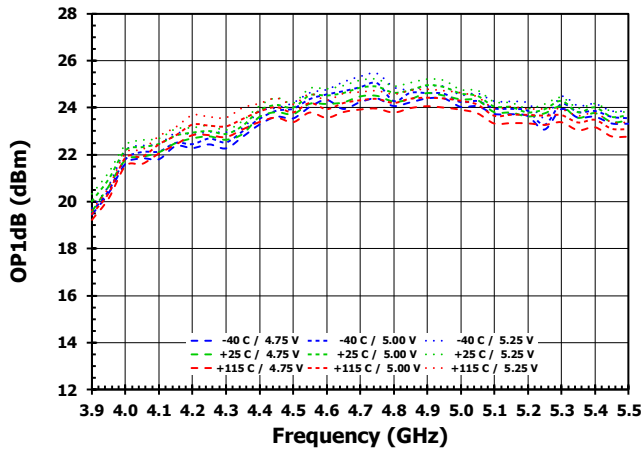


Figure 96. Output Compression - High Power Mode

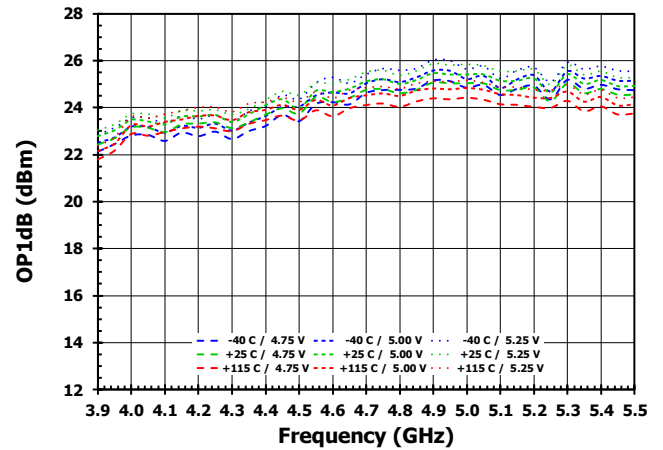


Figure 97. Noise Figure - Low Power Mode

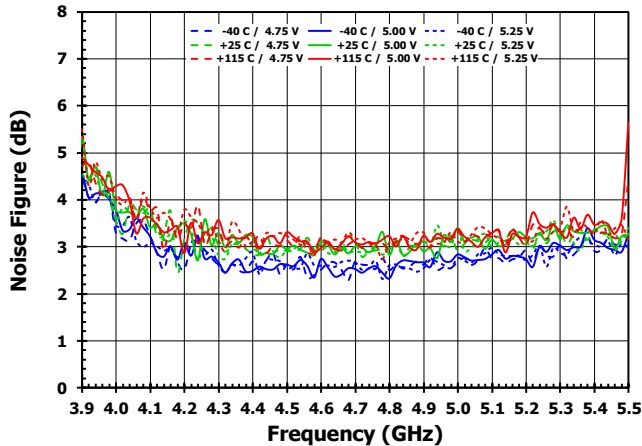
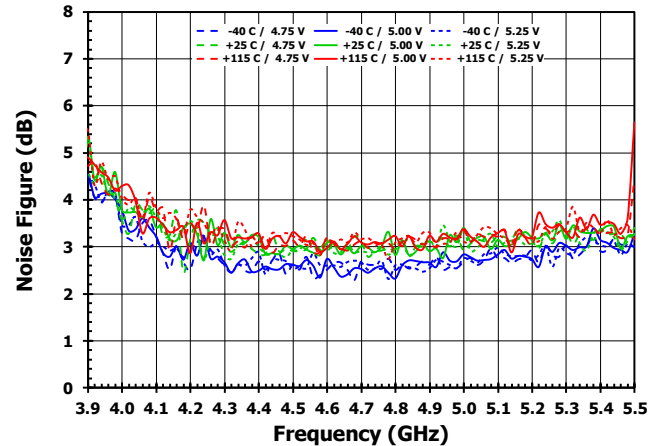


Figure 98. Noise Figure - High Power Mode



## Standby

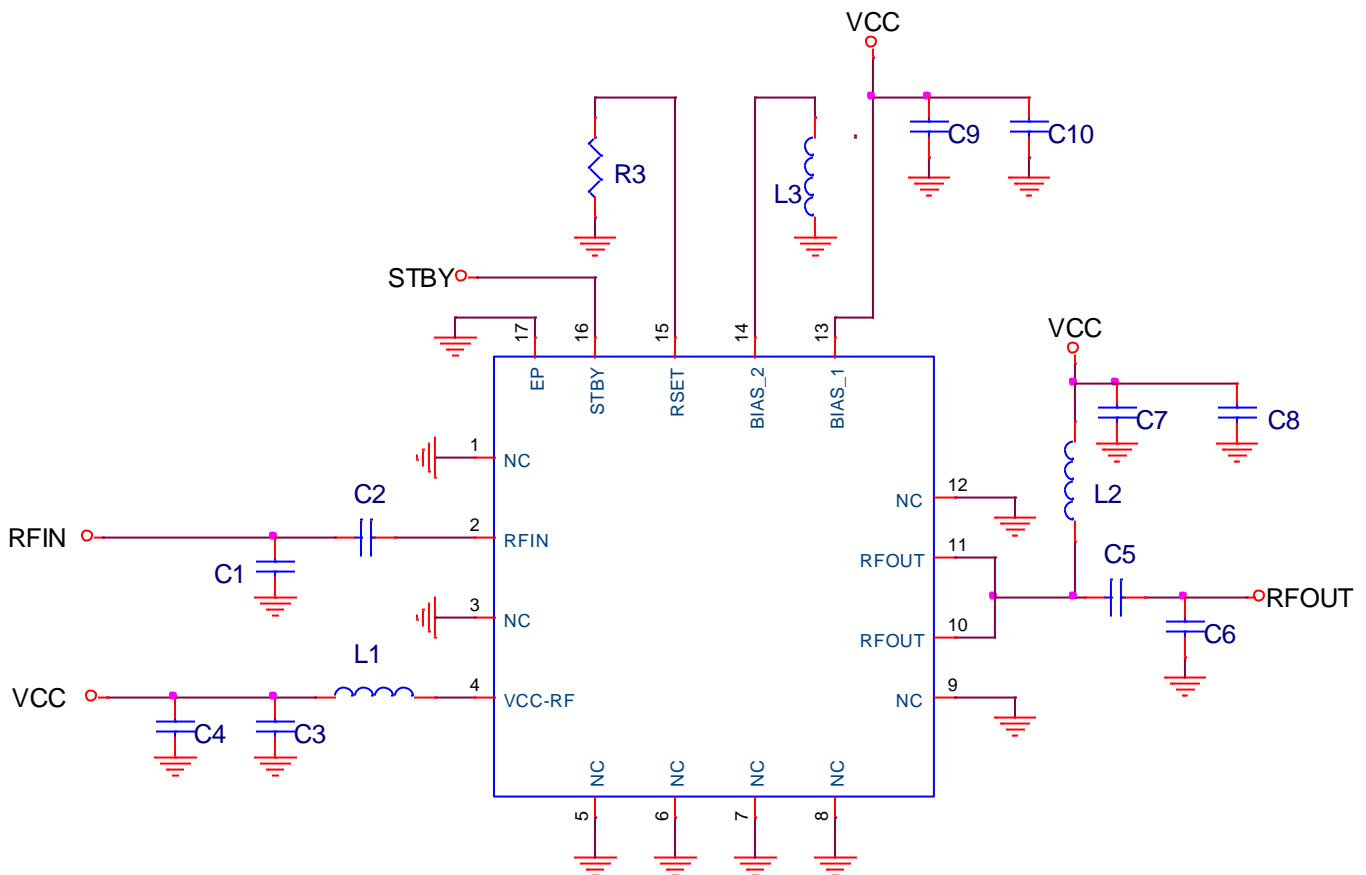
The F1478 can be turned off for low current consumption. This is done by applying a logic voltage to pin 16 using Table 14.

**Table 14. Standby Truth Table**

STBY	Condition
Logic HIGH	Full operation
Logic LOW	Amplifier OFF

## Typical Application Circuit

**Figure 99. Typical Application Circuit**



Note 1: All external components are size 0402 *except* C4, C8, and C10. These three capacitors are 0603 components as per the layout shown in Figure 100. Although these capacitors are sized as 0603 on the EVKit, comparable 0402 devices can be used instead.

Note 2: For the 3.3 to 3.8GHz and 4.4 to 5.0GHz bands of operation, the optimal input tuning topology uses a SHUNT INDUCTOR for C1. If there is a DC bias associated with the RF output from a preceding stage, then an additional DC block should be used to prevent a DC short through the shunt inductor placed at C1.

## Evaluation Kit Picture

Figure 100. Top View

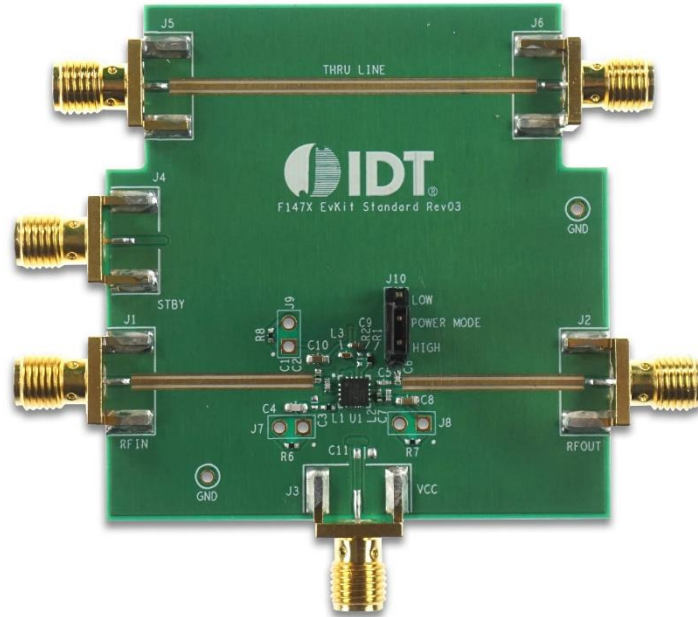
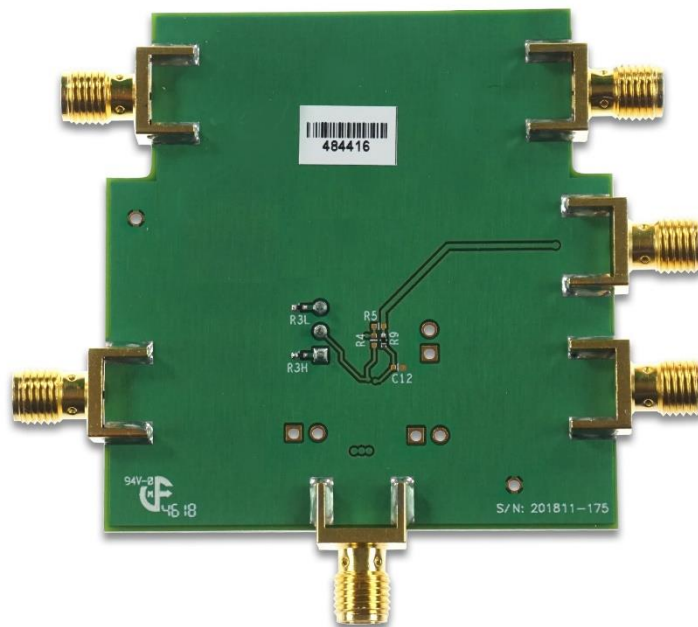
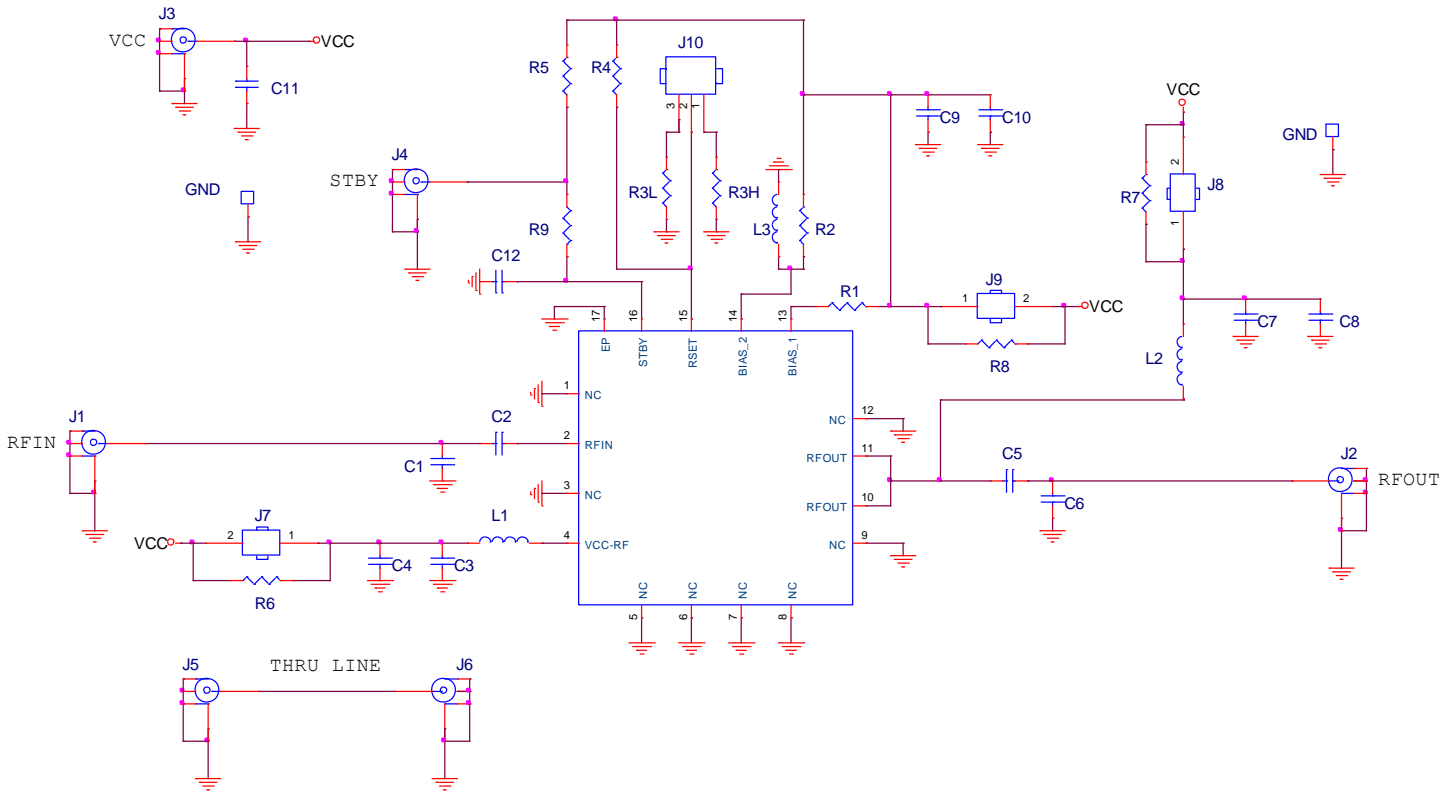


Figure 101. Bottom View



## Evaluation Kit Circuit

Figure 102. Electrical Schematic for the Evaluation Board



**Table 15. Bill of Material (BOM)**

Part Reference	QTY	Description	Manufacturer Part #	Manufacturer
C1	1	Band 2p0: 0.9pF $\pm$ 0.1pF, 50V, C0G Ceramic Capacitor (0402)	GJM1555C1HR90B	Murata
		Band 2p5: 0.5pF $\pm$ 0.05pF, 50V, C0G Ceramic Capacitor (0402)	GRM1555C1HR50W	
		Band 3p5: 2.2nH $\pm$ 0.2pF, 900mA Ind (0402)	LQG15HS2N2C02D	Murata
		Band 4p7: 1.8nH $\pm$ 0.2pF, 950mA Ind (0402)	LQG15HS1N8C02D	
C2	1	Band 2p0: 0.1 $\mu$ F $\pm$ 5%, 16V, X7R Ceramic Capacitor (0402)	GRM155R71C104K	Murata
		Band 2p5: 0.1 $\mu$ F $\pm$ 5%, 16V, X7R Ceramic Capacitor (0402)	GRM155R71C104K	
		Band 3p5: 1.5pF $\pm$ 0.05pF, 50V, C0G Ceramic Capacitor (0402)	GJM1555C1H1R5W	
		Band 4p7: 1.0pF $\pm$ 0.05pF, 50V, C0G Ceramic Capacitor (0402)	GJM1555C1H1R0WD	
C3	1	Band 2p0: 0.5pF $\pm$ 0.05pF, 50V, C0G Ceramic Capacitor (0402)	GRM1555C1HR50W	Murata
		Band 2p5: DNP (Do Not Populate)		
		Band 3p5: DNP (Do Not Populate)		
		Band 4p7: 1.1pF $\pm$ 0.1pF, 50V, C0G Ceramic Capacitor (0402)	GJM1555C1H1R1B	Murata
C4	1	Band 2p0: 0.1 $\mu$ F $\pm$ 5%, 50V, X8L Ceramic Capacitor (0603)	GCM188L81H104K	Murata
		Band 2p5: 0.1 $\mu$ F $\pm$ 5%, 50V, X8L C0G Ceramic Capacitor (0603)	GCM188L81H104K	
		Band 3p5: 5.1pF $\pm$ 0.25pF, 100V, C0G Ceramic Capacitor (0603)	GQM1885C2A5R1CB	
		Band 4p7: DNP (Do Not Populate)		
C5	1	Band 2p0: 47pF $\pm$ 5%, 50V, C0G Ceramic Capacitor (0402)	GRM1555C1H470J	Murata
		Band 2p5: 10pF $\pm$ 5%, 50V, C0G Ceramic Capacitor (0402)	GRM1555C1H100J	
		Band 3p5: 10pF $\pm$ 5%, 50V, C0G Ceramic Capacitor (0402)	GRM1555C1H100J	
		Band 4p7: 10pF $\pm$ 5%, 50V, C0G Ceramic Capacitor (0402)	GRM1555C1H100J	
C6	1	Band 2p0: 1.3pF $\pm$ 0.05pF, 50V, C0G Ceramic Capacitor (0402)	GJM1555C1H1R3W	Murata

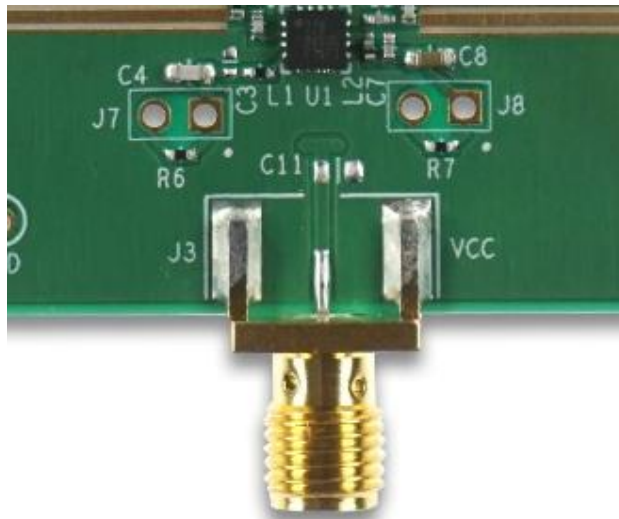
Part Reference	QTY	Description	Manufacturer Part #	Manufacturer
		<b>Band 2p5:</b> 1.2pF $\pm$ 0.05pF, 50V, C0G Ceramic Capacitor (0402)	GRM1555C1H1R2W	
		<b>Band 3p5:</b> 0.3pF $\pm$ 0.05pF%, 50V, C0G Ceramic Capacitor (0402)	GJM1555C1HR30W	
		<b>Band 4p7:</b> 0.3pF $\pm$ 0.05pF, 50V, C0G Ceramic Capacitor (0402)	GJM1555C1HR30W	
C7	1	10pF $\pm$ 5%, 50V, C0G Ceramic Capacitor (0402)	GRM1555C1H100J	Murata
C8	1	0.1 $\mu$ F $\pm$ 5%, 50V, X8L Ceramic Capacitor (0603)	GCM188L81H104K	Murata
C9	1	0.1 $\mu$ F $\pm$ 5%, 16V, X7R Ceramic Capacitor (0402)	GRM155R71C104K	Murata
C10	1	0.1 $\mu$ F $\pm$ 5%, 50V, X8L Ceramic Capacitor (0603)	GCM188L81H104K	Murata
L1	1	<b>Band 2p0:</b> 7.5nH $\pm$ 3%, 550mA Inductor (0402)	LQG15HS7N5H02	Murata
		<b>Band 2p5:</b> 3.0nH $\pm$ 0.3nH, 800mA Inductor (0402)	LQG15HS3N0S02	
		<b>Band 3p5:</b> 7.5 $\Omega$ $\pm$ 5%, 1/10W, Chip Resistor (0402)	ERJ-2GEJ7R5X	Panasonic
		<b>Band 4p7:</b> 2.5 $\Omega$ $\pm$ 5%, 1/10W, Chip Resistor (0402)	ERJ-2GEJ2R4X	
L2	1	<b>Band 2p0:</b> 27nH $\pm$ 5%, 350mA Inductor (0402)	LQG15HS27NJ02	Murata
		<b>Band 2p5:</b> 18nH $\pm$ 5%, 400mA, Inductor (0402)	LQG15HS18NJ02	
		<b>Band 3p5:</b> 10nH $\pm$ 5%, 500mA, Inductor (0402)	LQG15HS10NJ02	
		<b>Band 4p7:</b> 6.8nH $\pm$ 5%, 600mA, Inductor (0402)	LQG15HS6N8J02	
L3	1	<b>Band 2p0:</b> 6.8nH $\pm$ 5%, 600mA Inductor (0402)	LQG15HS6N8J02	Murata
		<b>Band 2p5:</b> 3.9nH $\pm$ 0.3nH, 750mA Inductor (0402)	LQG15HS3N9S02	
		<b>Band 3p5:</b> 2.4nH $\pm$ 0.1nH, 220mA Inductor (0402)	LQP15MN2N4B02	
		<b>Band 4p7:</b> 1.2nH $\pm$ 0.1nH, 390mA Inductor (0402)	LQP15MN1N2B02	
R1, R6 - R9	1	0 $\Omega$ , 1/10W, Resistor (0402)	ERJ-2GE0R00X	Panasonic
R2, R4, R5	0	DNP (Do Not Populate)		
R3	1	<b>High Power Mode:</b> 10k $\Omega$ $\pm$ 1%, 0.1W, Resistor (0402)	ERJ-2RKF1002X	Panasonic
		<b>Low Power Mode:</b> 16k $\Omega$ $\pm$ 1%, 0.1W, Resistor (0402)	ERJ-2RKF1602X	Panasonic
U1	1	F1478 High Gain RF Amplifier	F1478NLGA	IDT

## Evaluation Kit Operation

### Power Supply Setup

Set up a power supply in the voltage range of 3.0V to 5.5V, preferably around 5.0V, with the power supply output disabled. Apply the voltage through the J3 connector as shown in Figure 103.

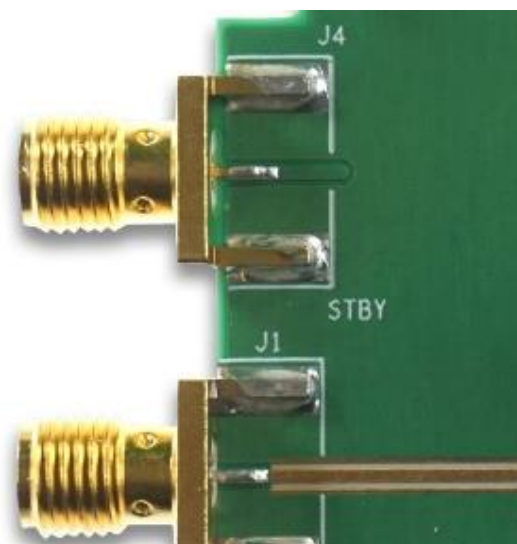
**Figure 103. Power Supply Connections**



### Standby

Set up a power supply in the voltage range of 1.5V to 5.5V with the power supply output disabled. Apply the voltage through the J4 connector as shown in Figure 104.

**Figure 104. Standby Connection**



## Power-On Procedure

Set up the voltage supplies and Evaluation Board as described in Power Supply Setup

1. Enable the power supply
2. Turn on the power supply

## Power-Off Procedure

1. Turn off the power supply
2. Disable the power supply

## Application Information

The F1478 has been optimized for use in high performance RF applications ranging from 1.8GHz to 5.0GHz. Separate, broadband tuning options are recommended for operating the device within four sub-bands, specifically 1.8GHz to 2.2GHz (Band 2p0), 2.3GHz to 2.7GHz (Band 2p5), 3.3GHz to 3.8GHz (Band 3p5), and 4.4GHz to 5.0GHz (Band 4p7).

## Performance

The high performance is obtained by tuning the F1478 for the input match (RFIN, pin 2), output match (RFOUT, pins 10 and 11), and the interstage  $V_{CC}$  (pin 4). RSET (pin 15) is used to set the overall current of the amplifier by setting a resistor to ground. The current will affect all of the amplifier parameters. Bias 2 (pin 13), Bias 1 (pin 14) will mainly affect the intermodulation parameters.

When designing a layout keep the components as close to the package as possible. Use the application circuit shown in Figure 99 and the best RF practices to achieve optimum performance.

## Standby Mode (STBY)

The F1478 uses a power down feature for power savings. Connecting pin 16 to a logic HIGH (or leaving the pin unconnected) enables the device. With a logic LOW applied to pin 16, the amplifier is placed in standby mode. The Standby mode is a high isolation state. The level of this isolation is not specified and is dependent on the device.

## Digital Pin Voltage and Resistance Values

Table 16 provides the open-circuit DC voltage referenced to ground and resistance values for each of the control pins listed.

**Table 16. Digital Pin Voltages and Resistance**

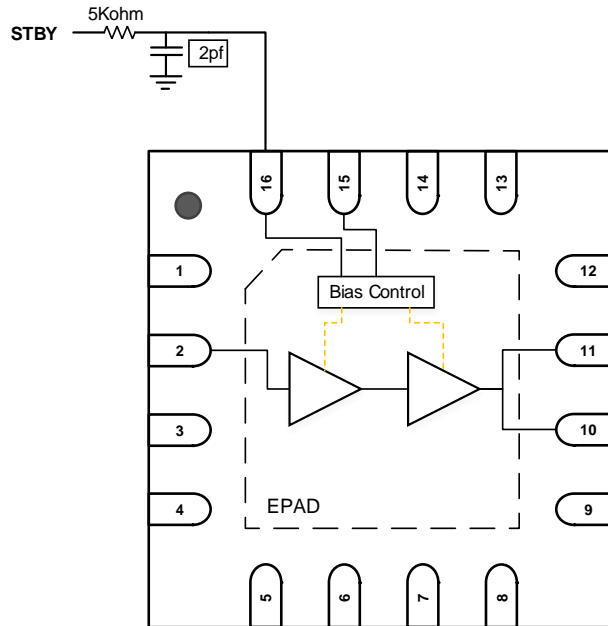
Pin	Name	Open Circuit DC Voltage	Internal Connection
16	STBY	$V_{CC}$	100k $\Omega$ pull-up resistor to $V_{CC}$

## Power Supplies

A common  $V_{CC}$  power supply should be used for all power supply pins. To minimize noise and fast transients, add de-coupling capacitors to all supply pins. Supply noise can degrade noise figure and fast transients can trigger ESD clamps causing them to fail. Supply voltage change or transients should have a slew rate smaller than  $1V / 20\mu s$ . In addition, all control pins should remain at 0V ( $\pm 0.3V$ ) while the supply voltage ramps or while it returns to zero.

If control signal integrity is a concern and clean signals cannot be guaranteed due to overshoot, undershoot, ringing, etc., the following circuit is recommended at the input of each control pin. This applies to the standby pin (16) as shown below. Note the recommended resistor and capacitor values do not necessarily match the EVKit BOM for the case of poor control signal integrity. For multiple devices driven by a single control line, the component values will need to be adjusted accordingly so as not to load down the control line.

**Figure 105. Control Pin Interface for Signal Integrity**



## Package Outline Drawings

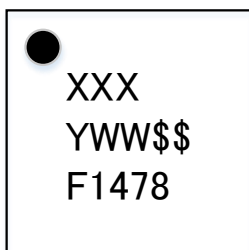
The package outline drawings are appended at the end of this document and are accessible from the link below. The package information is the most current data available.

[www.idt.com/document/psc/16-vfqfn-package-outline-drawing-30-x-30-x-090-mm-050mm-pitch-160-x-160-mm-epad-nlg16p3](http://www.idt.com/document/psc/16-vfqfn-package-outline-drawing-30-x-30-x-090-mm-050mm-pitch-160-x-160-mm-epad-nlg16p3)

## Ordering Information

Orderable Part Number	Package	MSL Rating	Shipping Packaging	Temperature
F1478NLGA	3 × 3 × 0.9 mm 16-pin VFQFPN	MSL 3	Tray	-40° to +115°C
F1478NLGA8	3 × 3 × 0.9 mm 16-pin VFQFPN	MSL 3	Tape and Reel	-40° to +115°C
F1478EVB-2p0	Evaluation Board for Band 2p0 – 1.8GHz to 2.2GHz			
F1478EVB-2p5	Evaluation Board for Band 2p5 – 2.3GHz to 2.7GHz			
F1478EVB-3p5	Evaluation Board for Band 3p5 – 3.3GHz to 3.9GHz			
F1478EVB-4p7	Evaluation Board for Band 4p7 – 4.4GHz to 5.0GHz			

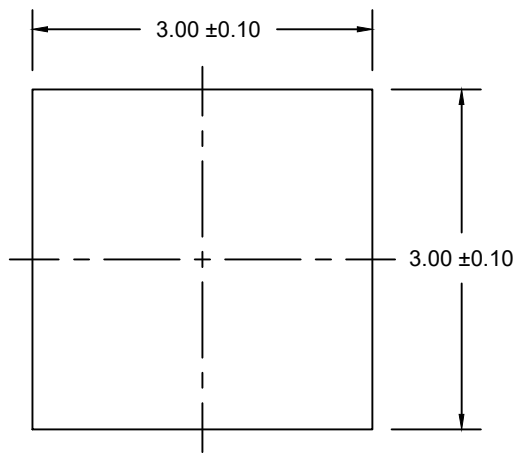
## Marking Diagram



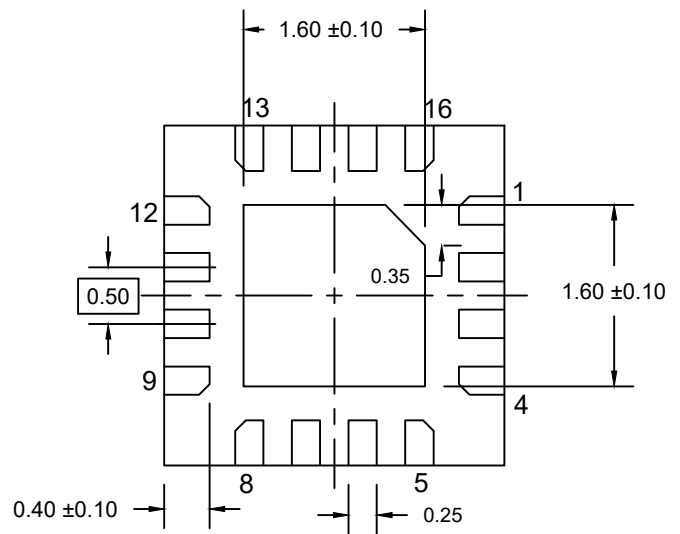
- Line 1 “XXX” represents the last three digits of the lot number.
- Line 2 “YWW” has one digit for the year and two digits for week that the part was assembled. “\$\$” denotes the assembly site.
- Line 3 “F1478” is the part number.

## Revision History

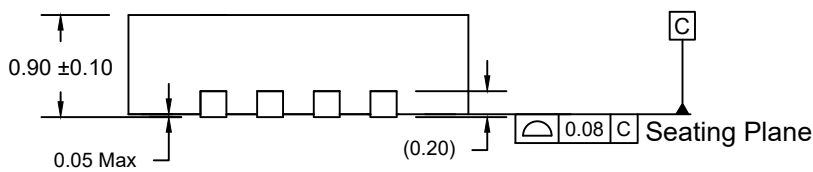
Revision Date	Description of Change
March 29, 2019	Initial release.



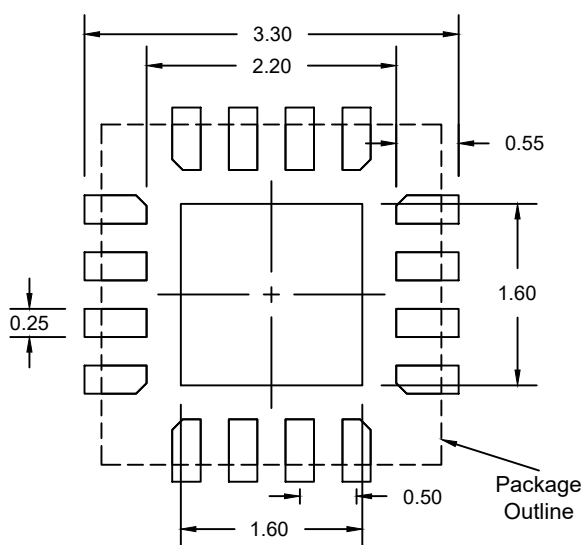
Top View



Side View



Side View



Recommended Land Pattern  
(PCB Top View, NSMD Design)

Notes:

1. JEDEC compatible.
2. All dimensions are in mm. and angle are in degrees.
3. Use  $\pm 0.05$  mm for the non-toleranced dimensions.
4. Numbers in ( ) are for references only.

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